

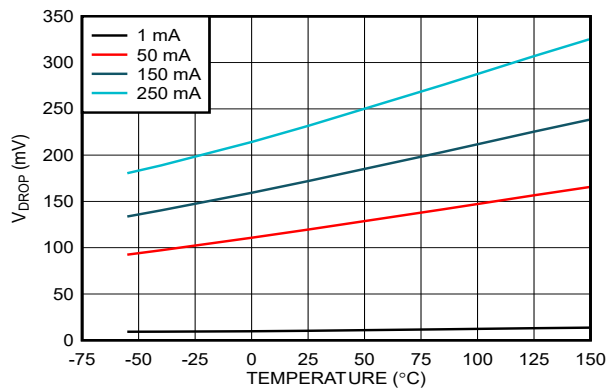
LP2992 采用 SOT-23 和 WSON 封装、旨在与超低 ESR 输出电容器配合使用的 微功耗 250mA 低噪声超低压降稳压器

1 特性

- V_{IN} 范围 (新芯片) : 2.5V 至 16V
- V_{OUT} 范围 (新芯片) :
 - 1.2V 至 5.0V (固定值, 100mV 阶跃)
- V_{OUT} 精度 :
 - A 级旧芯片为 $\pm 1\%$
 - 标准级旧芯片为 $\pm 1.5\%$
 - $\pm 0.5\%$ (新芯片)
- 在整个负载和温度范围内的输出精度为 $\pm 1\%$ (新芯片)
- 输出电流 : 高达 250mA
- 低 I_Q (新芯片) : $I_{LOAD} = 0mA$ 时为 $69 \mu A$
- 低 I_Q (新芯片) : $I_{LOAD} = 250mA$ 时为 $875 \mu A$
- 关断电流 :
 - $0.01 \mu A$ (典型值, 旧芯片)
 - $1.12 \mu A$ (典型值, 新芯片)
- 低噪声 : $30 \mu V_{RMS}$ (具有 10nF 旁路电容器)
- 输出电流限制和热保护
- 与 $2.2 \mu F$ 陶瓷电容器搭配使用时可保持稳定
- 高 PSRR : 1kHz 频率下为 70dB, 1MHz 频率下为 40dB
- 工作结温 : $-40^\circ C$ 至 $+125^\circ C$
- 封装 : 5 引脚 SOT-23 (DBV)

2 应用

- 洗衣机和烘干机
- 陆地移动无线电
- 有源天线系统 mMIMO
- 无线电动工具
- 电机驱动器和控制板



新芯片的压降电压与温度间的关系

3 说明

LP2992 是一款宽输入、固定输出、低噪声、低压降稳压器, 支持 2.5V 至 16V 的输入电压范围和高达 250mA 的负载电流。LP2992 支持 1.2V 至 5.0V 的输出范围 (新芯片)。

此外, LP2992 (新芯片) 在整个负载和温度范围内具有 1% 的输出精度, 可满足低压微控制器 (MCU) 和处理器的需求。

$30 \mu V_{RMS}$ 的低输出噪声 (带 10nF 旁路电容器) 以及 1kHz 时大于 70dB 和 1MHz 时大于 40dB 的宽带宽 PSRR 性能有助于衰减上游直流/直流转换器的开关频率, 并尽可能减少后置稳压器滤波。

内部软启动时间和电流限制保护可减小启动期间的浪涌电流, 从而尽可能降低输入电容。还包括标准保护特性, 例如过流和过热保护。

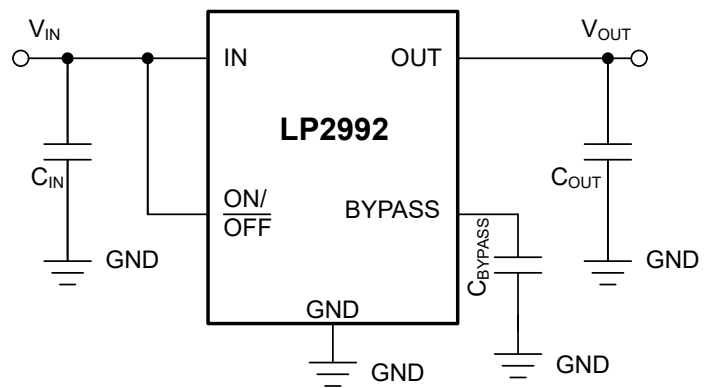
LP2992 采用 5 引脚、2.9mm × 2.8mm SOT-23 (DBV) 封装。

封装信息

器件型号	封装 ⁽¹⁾	封装尺寸 ⁽²⁾
LP2992	DBV (SOT-23, 5)	2.9mm × 2.8mm
	NGD (WSON, 6)	2.92mm × 3.29mm

(1) 如需更多信息, 请参阅 [机械、封装和可订购信息](#)。

(2) 封装尺寸 (长 × 宽) 为标称值, 并包括引脚 (如适用)。



典型应用电路



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4 Pin Configuration and Functions

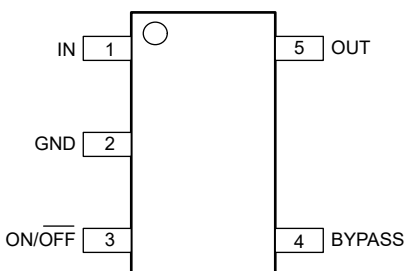


图 4-1. DBV Package, 5-Pin SOT-23 (Top View)

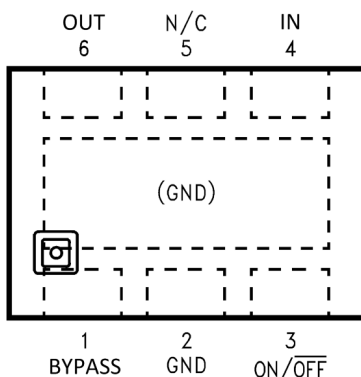


图 4-2. NGD Package, 6-Pin WSON (Top View) (Legacy Chip)

表 4-1. Pin Functions

PIN			TYPE	DESCRIPTION
NAME	DBV	NGD (Legacy chip only)		
BYPASS	4	1	I	BYPASS pin to achieve low noise performance. Connecting an external capacitor between BYPASS pin and ground reduces reference voltage noise. See the Recommended Operating Conditions table for more information.
GND	2	2	—	Ground
ON/OFF	3	3	I	Enable pin for the LDO. Driving the ON/OFF pin high enables the device. Driving this pin low disables the device. High and low thresholds are listed in the Electrical Characteristics table. Tie this pin to V _{IN} if unused.
IN	1	4	I	Input supply pin. Use a capacitor with a value of 1μF or larger from this pin to ground. See the Input and Output Capacitor Requirements section for more information.
OUT	5	6	O	Output of the regulator. Use a capacitor with a value of 2.2μF or larger from this pin to ground ⁽¹⁾ . See the Input and Output Capacitor Requirements section for more information.
N/C	—	5	—	No internal connection. Connect to GND or leave open. (Legacy chip only)
DAP	—	Exposed thermal pad	—	The exposed die attach pad on the bottom of the package must be connected to a copper thermal pad on the PCB at ground potential. Connect to ground potential or leave floating. Do not connect to any potential other than the same ground potential seen at device pin 2. (Legacy chip only)

(1) The nominal output capacitance must be greater than 1 μF. Throughout this document, the nominal derating on these capacitors is 50%. Make sure that the effective capacitance at the pin is greater than 1 μF.

5 Specifications

5.1 Absolute Maximum Ratings

over operating free-air temperature range (unless otherwise noted)^{(1) (2)}

		MIN	MAX	UNIT
V_{IN}	Continuous input voltage range (for legacy chip)	- 0.3	16	V
	Continuous input voltage range (for new chip)	- 0.3	18	
V_{OUT}	Output voltage range (for legacy chip)	- 0.3	9	V
	Output voltage range (for new chip)	- 0.3	$V_{IN} + 0.3$ or 9 (whichever is smaller)	
V_{BYPASS}	BYPASS pin voltage range (for new chip)	- 0.3	3	V
$V_{ON/OFF}$	ON/OFF pin voltage range (for legacy chip)	- 0.3	16	V
	ON/OFF pin voltage range (for new chip)	- 0.3	18	
Current	Maximum output	Internally limited		A
Temperature	Operating junction, T_J	- 55	150	°C
	Storage, T_{stg}	- 65	150	

- (1) Operation outside the Absolute Maximum Ratings may cause permanent device damage. Absolute Maximum Ratings do not imply functional operation of the device at these or any other conditions beyond those listed under Recommended Operating Conditions. If used outside the Recommended Operating Conditions but within the Absolute Maximum Ratings, the device may not be fully functional, and this may affect device reliability, functionality, performance, and shorten the device lifetime.
- (2) All voltages with respect to GND.

5.2 ESD Ratings

			VALUE (Legacy Chip)	VALUE (New Chip)	UNIT
$V_{(ESD)}$	Electrostatic discharge	Human body model (HBM), per ANSI/ESDA/JEDEC JS-001 ⁽¹⁾	±2000	±3000	V
		Charged device model (CDM), per JEDEC specification JESD22-C101 ⁽²⁾	±500	±1000	

- (1) JEDEC document JEP155 states that 2-kV HBM allows safe manufacturing with a standard ESD control process.
- (2) JEDEC document JEP157 states that 500-V CDM allows safe manufacturing with a standard ESD control process.

5.3 Recommended Operating Conditions

		MIN	NOM	MAX	UNIT
V_{IN}	Supply input voltage (for legacy chip)	2.2		16	V
	Supply input voltage (for new chip)	2.5		16	
V_{OUT}	Output voltage (for legacy chip)	1.2		10.0	V
	Output voltage (for new chip)	1.2		5.0	
V_{BYPASS}	Bypass voltage		1.2		V
$V_{ON/OFF}$	Enable voltage (for legacy chip)	0		V_{IN}	V
	Enable voltage (for new chip)	0		16	
I_{OUT}	Output current	0		250	mA
C_{IN} ⁽¹⁾	Input capacitor		1		μF
C_{OUT}	Output capacitance (for legacy chip)	2.2	4.7		μF
	Output capacitance (for new chip) ⁽¹⁾	1	2.2	200	
C_{OUT} ESR ⁽³⁾	Output capacitor ESR (for new chip) ⁽²⁾	0		1	Ω
T_J	Operating junction temperature	- 40		125	°C

- (1) All capacitor values are assumed to derate to 50% of the nominal capacitor value. Maintain an effective output capacitance of 1 μF minimum for stability.
- (2) Details related to supported ESR range for the legacy chip are available in *Recommended Capacitors for the Legacy Chip*.
- (3) Maximum supported ESR range for new chip is 1Ω. For output capacitor with higher ESR values, place a low ESR MLCC capacitor with value of 100nF, close to the output pin of the LDO.

5.4 Thermal Information

THERMAL METRIC ⁽²⁾ ⁽¹⁾		Legacy Chip Only	Legacy Chip	New Chip	UNIT
		NGD (WSON) ⁽³⁾	DBV (SOT23-5)	DBV (SOT23-5)	
		6 PINS	5 PINS	5 PINS	
$R_{\theta JA}$	Junction-to-ambient thermal resistance	72.3	169.7	178.6	°C/W
$R_{\theta JC(top)}$	Junction-to-case (top) thermal resistance	81.6	122.6	77.9	°C/W
$R_{\theta JB}$	Junction-to-board thermal resistance	39.5	29.9	47.2	°C/W
ψ_{JT}	Junction-to-top characterization parameter	2	16.7	15.9	°C/W
ψ_{JB}	Junction-to-board characterization parameter	39.2	29.4	46.9	°C/W
$R_{\theta JC(bot)}$	Junction-to-case (bottom) thermal resistance	11.6	–	–	°C/W

- (1) For more information about traditional and new thermal metrics, see the [Semiconductor and IC Package Thermal Metrics](#) application note.
- (2) Thermal performance results are based on the JEDEC standard of 2s2p PCB configuration. These thermal metric parameters can be further improved by 35-55% based on thermally optimized PCB layout designs. See the analysis of the [Impact of board layout on LDO thermal performance](#) application report.
- (3) The PCB for the NGD (WSON) package $R_{\theta JA}$ includes two (2) thermal vias under the exposed thermal pad per EIA/JEDEC JESD51-5.

5.5 Electrical Characteristics

specified at $T_J = 25^\circ\text{C}$, $V_{IN} = V_{OUT(nom)} + 1.0\text{ V}$ or $V_{IN} = 2.5\text{ V}$ (whichever is greater), $I_{OUT} = 1\text{ mA}$, $V_{ON/OFF} = 2\text{ V}$, $C_{IN} = 1.0\text{ }\mu\text{F}$, and $C_{OUT} = 2.2\text{ }\mu\text{F}$ (unless otherwise noted)

PARAMETER		TEST CONDITIONS		MIN	TYP	MAX	UNIT
ΔV_{OUT}	Output voltage tolerance	$I_L = 1\text{ mA}$	Legacy chip (standard grade)	- 1.5		1.5	%
			Legacy chip (A grade)	- 1.0		1.0	
			New chip	- 0.5		0.5	
		$1\text{ mA} \leq I_L \leq 50\text{ mA}$	Legacy chip (standard grade)	- 2.5		2.5	
			Legacy chip (A grade)	- 1.5		1.5	
			New chip	- 0.5		0.5	
		$1\text{ mA} \leq I_L \leq 50\text{ mA}, -40^\circ\text{C} \leq T_J \leq 125^\circ\text{C}$	Legacy chip (standard grade)	- 3.5		3.5	
			Legacy chip (A grade)	- 2.5		2.5	
			New chip	- 1		1	
		$1\text{ mA} \leq I_L \leq 250\text{ mA}$	Legacy chip (standard grade)	- 4		4	
			Legacy chip (A grade)	- 3.5		3.5	
			New chip	- 0.5		0.5	
		$1\text{ mA} \leq I_L \leq 250\text{ mA}, -40^\circ\text{C} \leq T_J \leq 125^\circ\text{C}$	Legacy chip (standard grade)	- 5		5	
			Legacy chip (A grade)	- 4.5		4.5	
			New chip	- 1		1	
$\Delta V_{OUT}(\Delta V_{IN})$	Line regulation	$V_{O(NOM)} + 1\text{ V} \leq V_{IN} \leq 16\text{ V}$	Legacy chip		0.007	0.014	% / V
			New chip		0.002	0.014	
		$V_{O(NOM)} + 1\text{ V} \leq V_{IN} \leq 16\text{ V}, -40^\circ\text{C} \leq T_J \leq 125^\circ\text{C}$	Legacy chip		0.007	0.032	
			New chip		0.002	0.032	
$V_{IN(MIN)}$	Minimum input voltage required to maintain output regulation		Legacy chip		2.05	V	
			New chip		2.05		
	Minimum input voltage required to maintain output regulation	$-40^\circ\text{C} \leq T_J \leq 125^\circ\text{C}$	Legacy chip		2.2		
			New chip		2.35		

5.5 Electrical Characteristics (续)

specified at $T_J = 25^\circ\text{C}$, $V_{IN} = V_{OUT(nom)} + 1.0\text{ V}$ or $V_{IN} = 2.5\text{ V}$ (whichever is greater), $I_{OUT} = 1\text{ mA}$, $V_{ON/OFF} = 2\text{ V}$, $C_{IN} = 1.0\text{ }\mu\text{F}$, and $C_{OUT} = 2.2\text{ }\mu\text{F}$ (unless otherwise noted)

PARAMETER		TEST CONDITIONS		MIN	TYP	MAX	UNIT
I_{GND}	GND pin current	$I_{OUT} = 0\text{ mA}$	Legacy chip	65	95		μA
			New chip	69	95		
		$I_{OUT} = 0\text{ mA}, -40^\circ\text{C} \leq T_J \leq 125^\circ\text{C}$	Legacy chip		125		
			New chip		123		
		$I_{OUT} = 1\text{ mA}$	Legacy chip	75	110		
			New chip	78	110		
		$I_{OUT} = 1\text{ mA}, -40^\circ\text{C} \leq T_J \leq 125^\circ\text{C}$	Legacy chip		170		
			New chip		140		
		$I_{OUT} = 50\text{ mA}$	Legacy chip	350	600		
			New chip	380	440		
		$I_{OUT} = 50\text{ mA}, -40^\circ\text{C} \leq T_J \leq 125^\circ\text{C}$	Legacy chip		1000		
			New chip		650		
		$I_{OUT} = 150\text{ mA}$	Legacy chip	850	1500		
			New chip	765	890		
		$I_{OUT} = 150\text{ mA}, -40^\circ\text{C} \leq T_J \leq 125^\circ\text{C}$	Legacy chip		2500		
			New chip		1060		
		$I_{OUT} = 250\text{ mA}$	Legacy Chip	1500	2300		
			New Chip	875	1010		
		$I_{OUT} = 250\text{ mA}, -40^\circ\text{C} \leq T_J \leq 125^\circ\text{C}$	Legacy Chip		4000		
			New Chip		1200		
		$V_{ON/OFF} < 0.3\text{ V}, V_{IN} = 16\text{ V}$	Legacy chip	0.01	0.8		
			New chip	1.25	1.75		
		$V_{ON/OFF} < 0.15\text{ V}, V_{IN} = 16\text{ V}, -40^\circ\text{C} \leq T_J \leq 125^\circ\text{C}$	Legacy chip	0.05	2		
			New chip	1.12	2.75		

5.5 Electrical Characteristics (续)

specified at $T_J = 25^\circ\text{C}$, $V_{IN} = V_{OUT(nom)} + 1.0\text{ V}$ or $V_{IN} = 2.5\text{ V}$ (whichever is greater), $I_{OUT} = 1\text{ mA}$, $V_{ON/OFF} = 2\text{ V}$, $C_{IN} = 1.0\text{ }\mu\text{F}$, and $C_{OUT} = 2.2\text{ }\mu\text{F}$ (unless otherwise noted)

PARAMETER		TEST CONDITIONS		MIN	TYP	MAX	UNIT
V_{DO}	Dropout voltage ⁽¹⁾	$I_{OUT} = 0\text{ mA}$	Legacy chip	0.5	2.5		mV
			New chip	1	2.75		
		$I_{OUT} = 0\text{ mA}, -40^\circ\text{C} \leq T_J \leq 125^\circ\text{C}$	Legacy chip		4		
			New chip		3		
		$I_{OUT} = 1\text{ mA}$	Legacy chip		5	9	
			New chip		11.5	14	
		$I_{OUT} = 1\text{ mA}, -40^\circ\text{C} \leq T_J \leq 125^\circ\text{C}$	Legacy chip		12		
			New chip		17		
		$I_{OUT} = 50\text{ mA}$	Legacy chip		100	125	
			New chip		120	145	
		$I_{OUT} = 50\text{ mA}, -40^\circ\text{C} \leq T_J \leq 125^\circ\text{C}$	Legacy chip		180		
			New chip		184		
		$I_{OUT} = 150\text{ mA}$	Legacy chip		260	325	
			New chip		180	198	
		$I_{OUT} = 150\text{ mA}, -40^\circ\text{C} \leq T_J \leq 125^\circ\text{C}$	Legacy chip		470		
			New chip		254		
		$I_{OUT} = 250\text{ mA}$	Legacy chip		450	575	
			New chip		225	260	
		$I_{OUT} = 250\text{ mA}, -40^\circ\text{C} \leq T_J \leq 125^\circ\text{C}$	Legacy chip		850		
			New chip		340		
$V_{ON/OFF}$	ON/OFF input voltage	Low = Output OFF	Legacy chip	0.55			V
			New chip	0.72			
		Low = Output OFF, $V_{OUT} + 1 \leq V_{IN} \leq 16\text{ V}, -40^\circ\text{C} \leq T_J \leq 125^\circ\text{C}$	Legacy chip		0.15		
			New chip		0.15		
		High = Output ON	Legacy chip	1.4			
			New chip	0.85			
$I_{ON/OFF}$	ON/OFF input current	$V_{ON/OFF} = 0\text{ V}, V_{OUT} + 1 \leq V_{IN} \leq 16\text{ V}, -40^\circ\text{C} \leq T_J \leq 125^\circ\text{C}$	Legacy chip			-2	μA
			New chip			-0.9	
$I_{ON/OFF}$	ON/OFF input current	$V_{ON/OFF} = 0\text{ V}$	Legacy chip	0.01			μA
			New chip	0.42			
$I_{O(PK)}$	Peak output current	$V_{OUT} \geq V_{O(NOM)} - 5\%$ (steady state)	Legacy chip	300	350		mA
			New chip	300	350		
$I_{O(SC)}$	Short output current	$R_L = 0\text{ }\Omega$ (steady state)	Legacy chip		400		
			New chip		375		
$\Delta V_O / \Delta V_{IN}$	Ripple rejection	$f = 1\text{ kHz}, C_{BYPASS} = 10\text{ nF}, C_{OUT} = 10\text{ }\mu\text{F}$	Legacy chip		45		dB
			New chip		78		
V_n	Output noise voltage	Bandwidth = 300 Hz to 50 kHz, $C_{BYPASS} = 10\text{ nF}, C_{OUT} = 2.2\text{ }\mu\text{F}, V_{OUT} = 3.3\text{ V}$	Legacy chip		30		μVRMS
			New chip		30		

(1) Dropout voltage (V_{DO}) is defined as the input-to-output differential at which the output voltage drops 100 mV below the value measured with a 1 V differential. V_{DO} is measured with $V_{IN} = V_{OUT(nom)} - 100\text{ mV}$ for fixed output devices.

5.6 Typical Characteristics

$C_{IN} = 1\mu F$, $C_{OUT} = 4.7\mu F$, $V_{IN} = V_{OUT(NOM)} + 1V$, $T_A = 25^\circ C$, and ON/OFF pin is tied to the IN pin (unless otherwise noted)

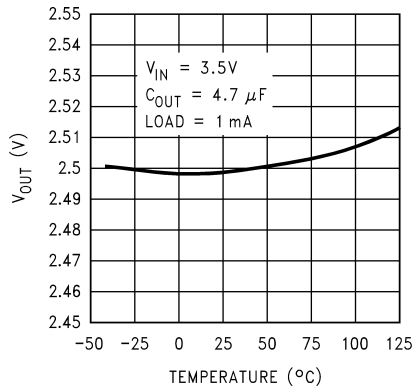


图 5-1. V_{OUT} vs Temperature (Legacy Chip)

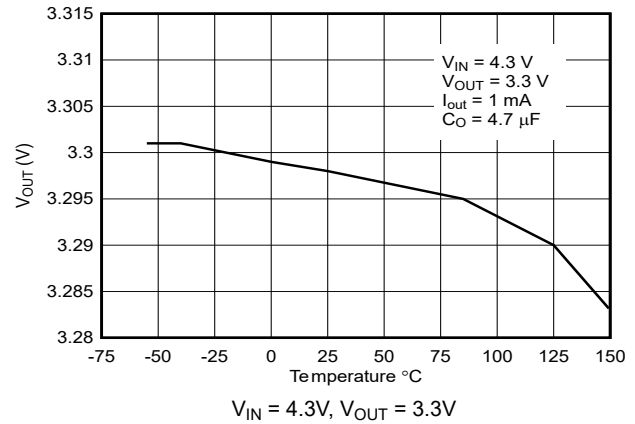


图 5-2. V_{OUT} vs Temperature (New Chip)

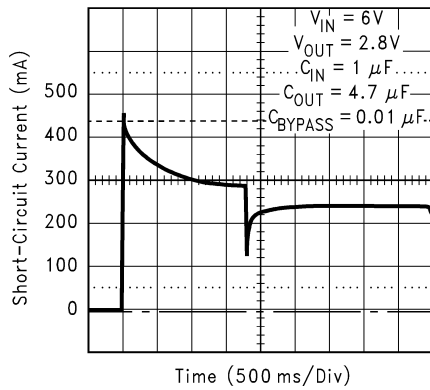


图 5-3. Short-Circuit Current (Legacy Chip)

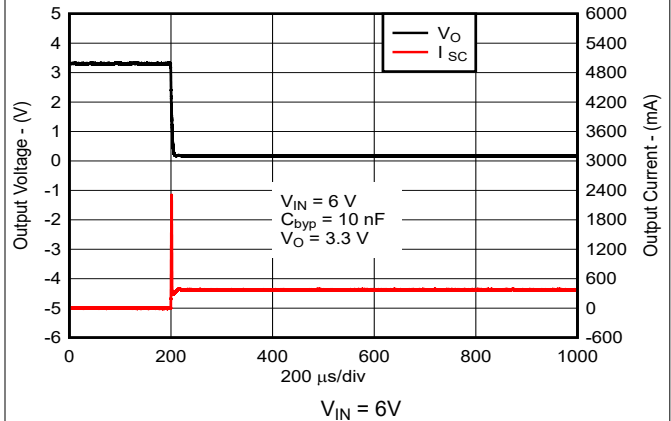


图 5-4. Short-Circuit Current vs Time (New Chip)

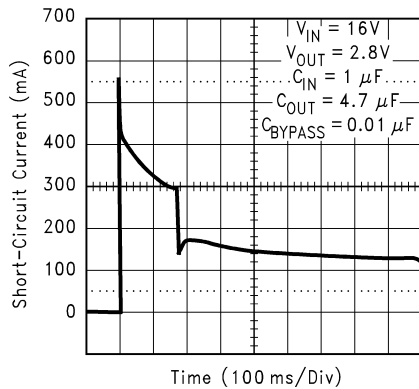


图 5-5. Short-Circuit Current (Legacy Chip)

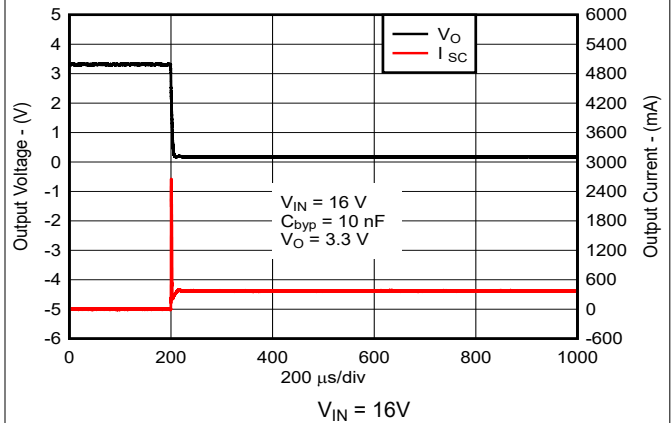


图 5-6. Short-Circuit Current vs Time (New Chip)

5.6 Typical Characteristics (continued)

$C_{IN} = 1\mu F$, $C_{OUT} = 4.7\mu F$, $V_{IN} = V_{OUT(NOM)} + 1V$, $T_A = 25^\circ C$, and ON/OFF pin is tied to the IN pin (unless otherwise noted)

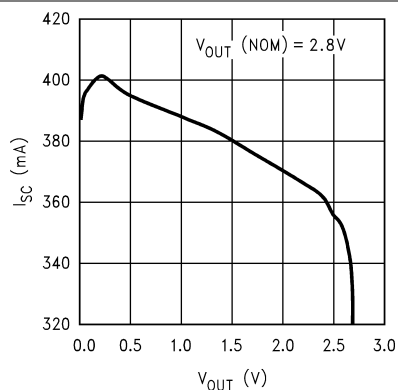


图 5-7. Short-Circuit Current vs Output Voltage (Legacy Chip)

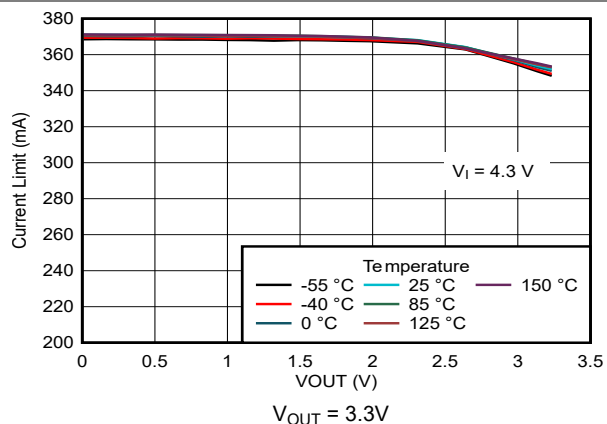


图 5-8. Short-Circuit Current vs Output Voltage (New Chip)

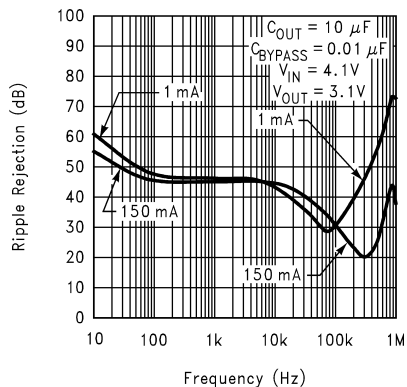


图 5-9. Ripple Rejection vs Frequency (Legacy Chip)

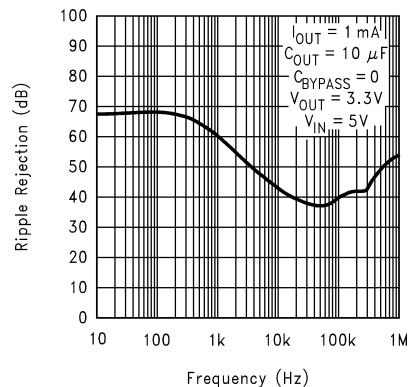


图 5-10. Ripple Rejection vs Frequency (Legacy Chip)

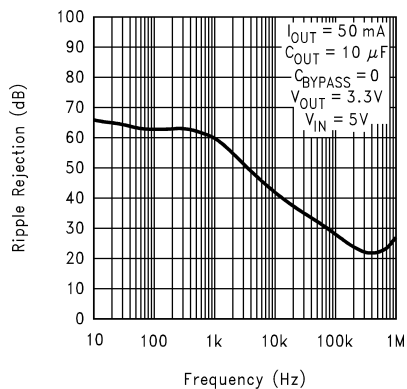


图 5-11. Ripple Rejection vs Frequency (Legacy Chip)

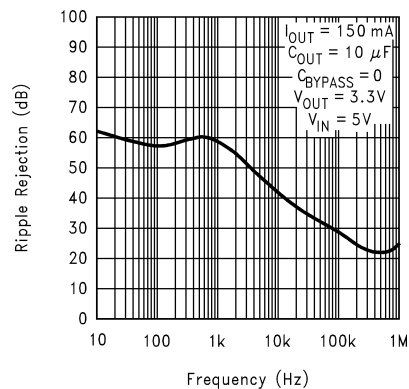


图 5-12. Ripple Rejection vs Frequency (Legacy Chip)

5.6 Typical Characteristics (continued)

$C_{IN} = 1\mu\text{F}$, $C_{OUT} = 4.7\mu\text{F}$, $V_{IN} = V_{OUT(NOM)} + 1\text{V}$, $T_A = 25^\circ\text{C}$, and ON/OFF pin is tied to the IN pin (unless otherwise noted)

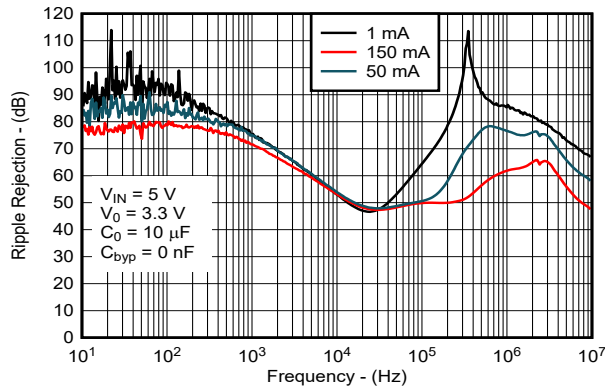


图 5-13. Ripple Rejection vs Frequency (New Chip)

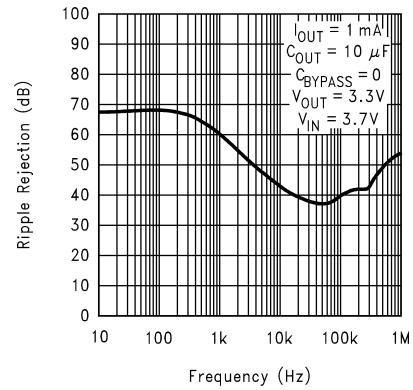


图 5-14. Ripple Rejection vs Frequency (Legacy Chip)

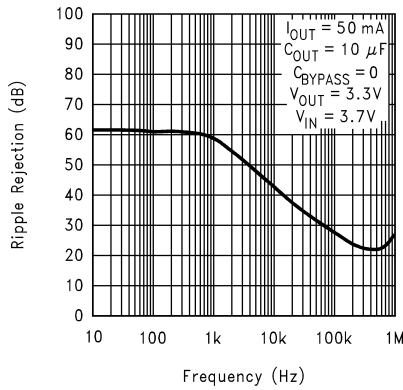


图 5-15. Ripple Rejection vs Frequency (Legacy Chip)

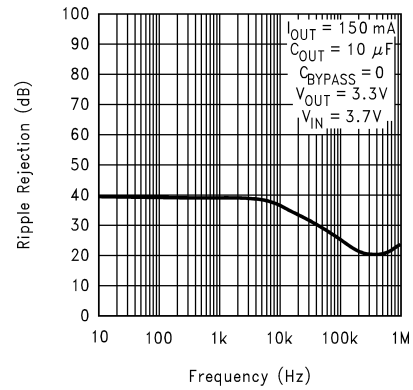


图 5-16. Ripple Rejection vs Frequency (Legacy Chip)

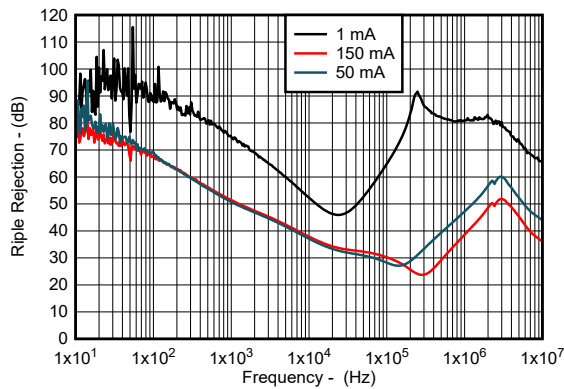


图 5-17. Ripple Rejection vs Frequency (New Chip)

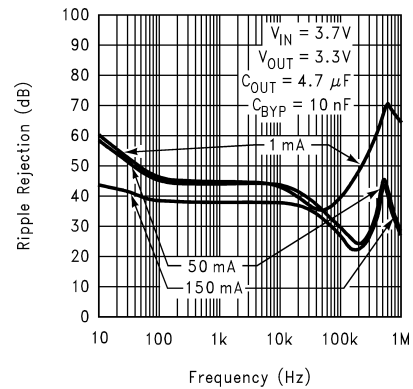


图 5-18. Ripple Rejection vs Frequency (Legacy Chip)

5.6 Typical Characteristics (continued)

$C_{IN} = 1\mu F$, $C_{OUT} = 4.7\mu F$, $V_{IN} = V_{OUT(NOM)} + 1V$, $T_A = 25^\circ C$, and ON/OFF pin is tied to the IN pin (unless otherwise noted)

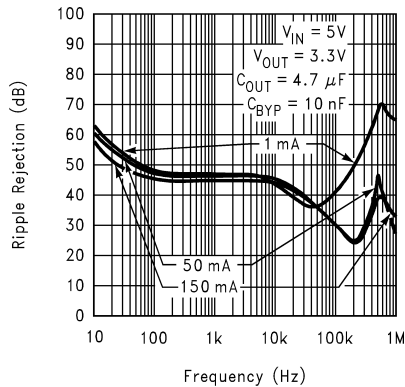
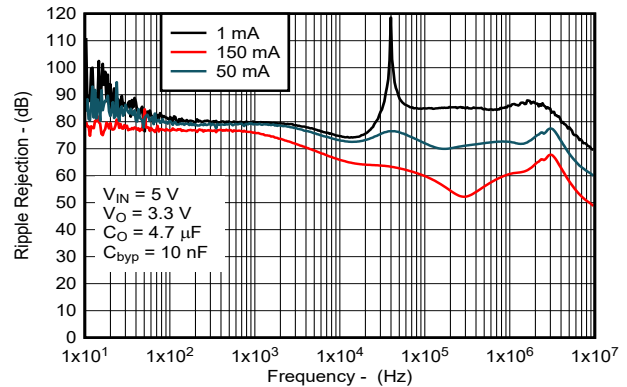


图 5-19. Ripple Rejection vs Frequency (Legacy Chip)



$V_{IN} = 5V$, $V_{OUT} = 3.3V$, $C_{OUT} = 10\mu F$, $C_{BYP} = 10nF$

图 5-20. Ripple Rejection vs Frequency (New Chip)

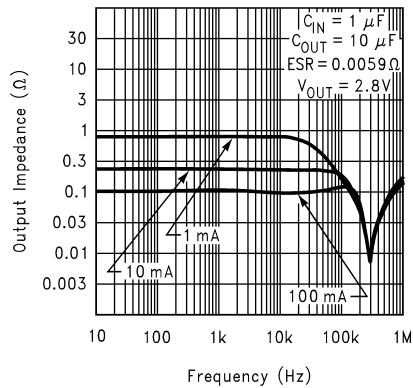


图 5-21. Output Impedance vs Frequency (Legacy Chip)

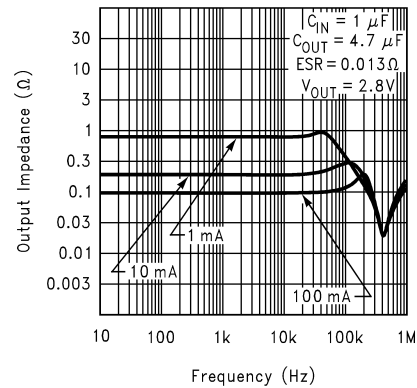


图 5-22. Output Impedance vs Frequency (Legacy Chip)

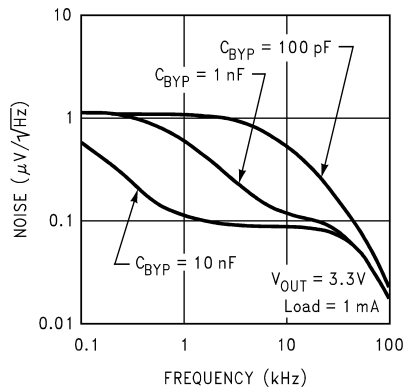


图 5-23. Output Noise Density (Legacy Chip)

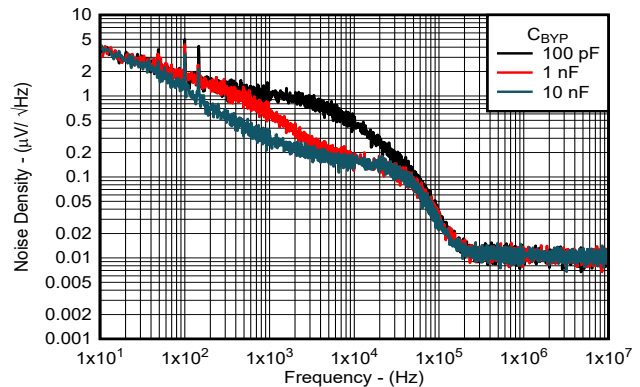


图 5-24. Output Noise Density vs Frequency (New Chip)

5.6 Typical Characteristics (continued)

$C_{IN} = 1\mu F$, $C_{OUT} = 4.7\mu F$, $V_{IN} = V_{OUT(NOM)} + 1V$, $T_A = 25^\circ C$, and ON/OFF pin is tied to the IN pin (unless otherwise noted)

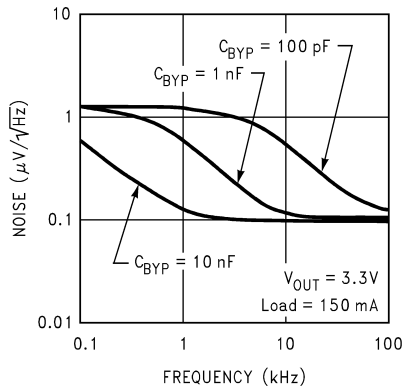


图 5-25. Output Noise Density (Legacy Chip)

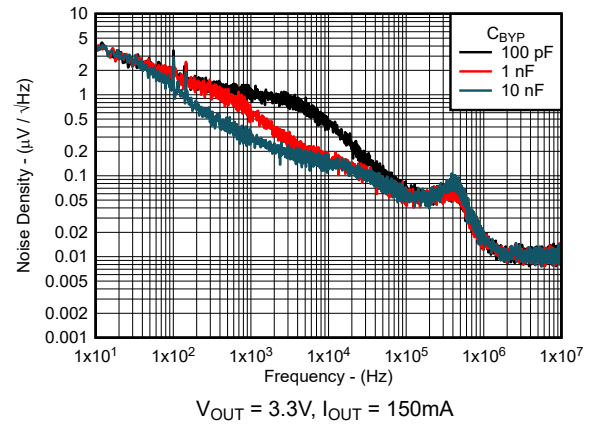


图 5-26. Output Noise Density vs Frequency (New Chip)

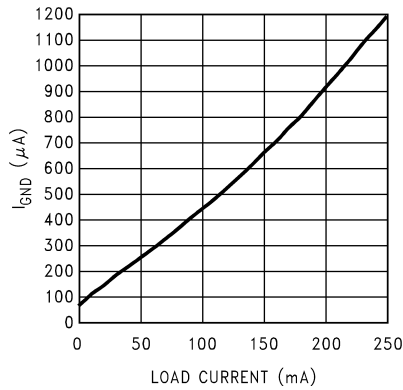


图 5-27. GND Pin vs Load Current (Legacy Chip)

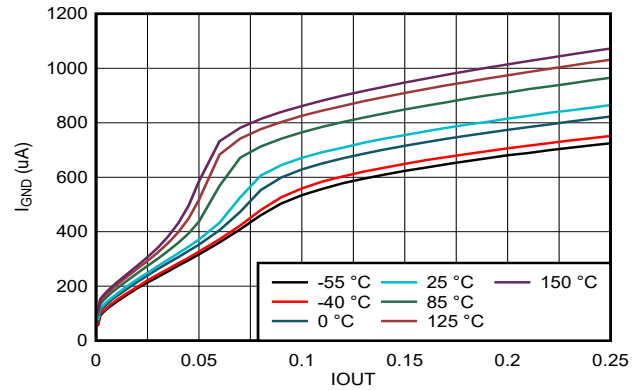


图 5-28. GND Pin vs Load Current (New Chip)

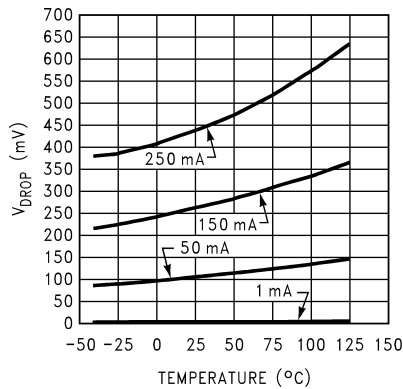


图 5-29. Dropout Voltage vs Temperature (Legacy Chip)

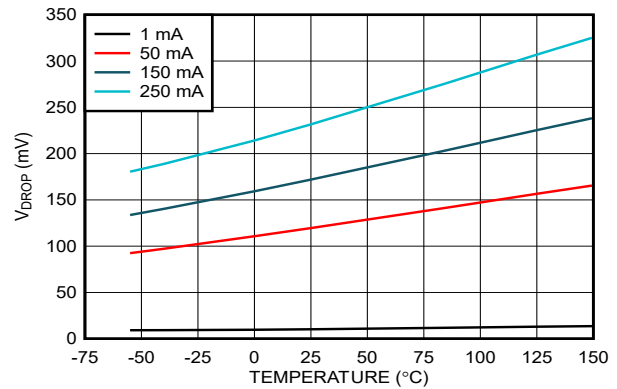


图 5-30. Dropout Voltage vs Temperature (New Chip)

5.6 Typical Characteristics (continued)

$C_{IN} = 1\mu F$, $C_{OUT} = 4.7\mu F$, $V_{IN} = V_{OUT(NOM)} + 1V$, $T_A = 25^\circ C$, and ON/OFF pin is tied to the IN pin (unless otherwise noted)

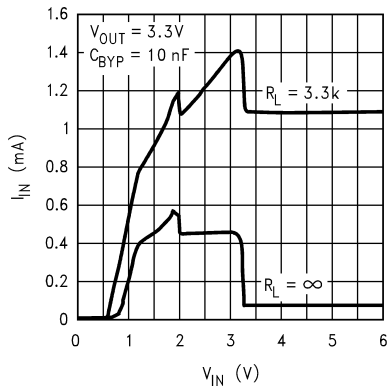


图 5-31. Input Current vs Input Voltage (Legacy Chip)

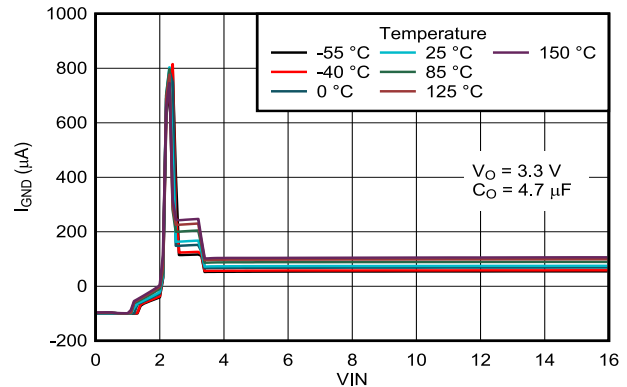


图 5-32. Input Current vs Input Voltage (New Chip)

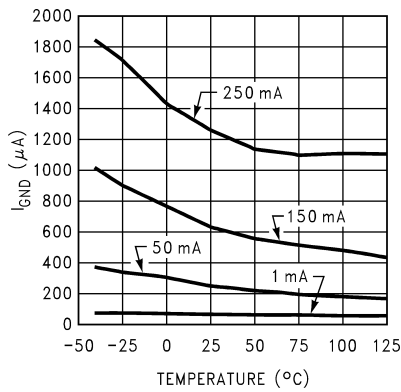


图 5-33. I_{GND} vs Load and Temperature (Legacy Chip)

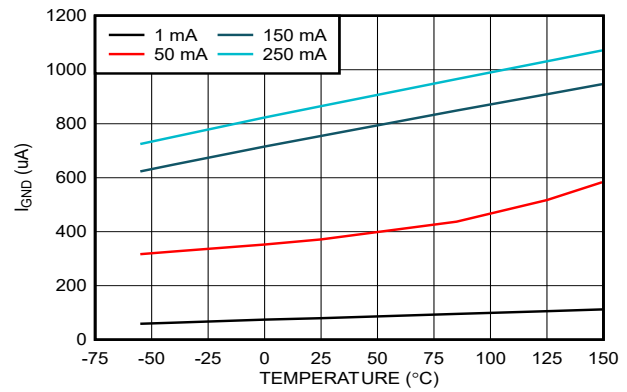


图 5-34. I_{GND} vs Load and Temperature (New Chip)

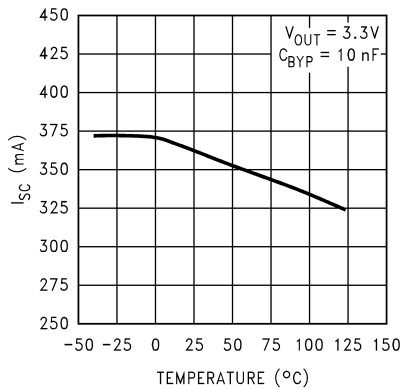


图 5-35. Short-Circuit Current vs Temperature (Legacy Chip)

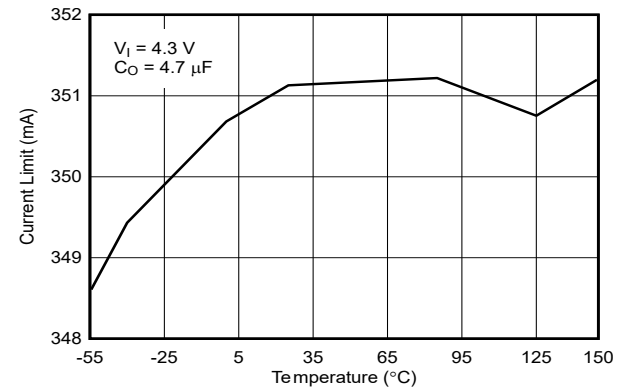


图 5-36. Short-Circuit Current vs Temperature (New Chip)

5.6 Typical Characteristics (continued)

$C_{IN} = 1\mu F$, $C_{OUT} = 4.7\mu F$, $V_{IN} = V_{OUT(NOM)} + 1V$, $T_A = 25^\circ C$, and ON/OFF pin is tied to the IN pin (unless otherwise noted)

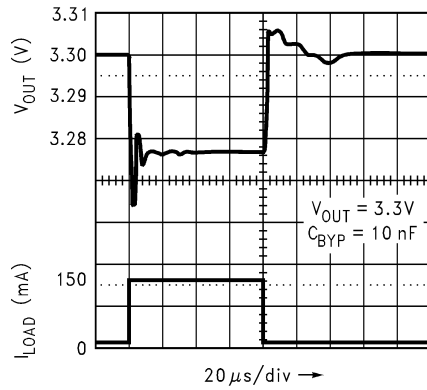


图 5-37. Load Transient Response (Legacy Chip)

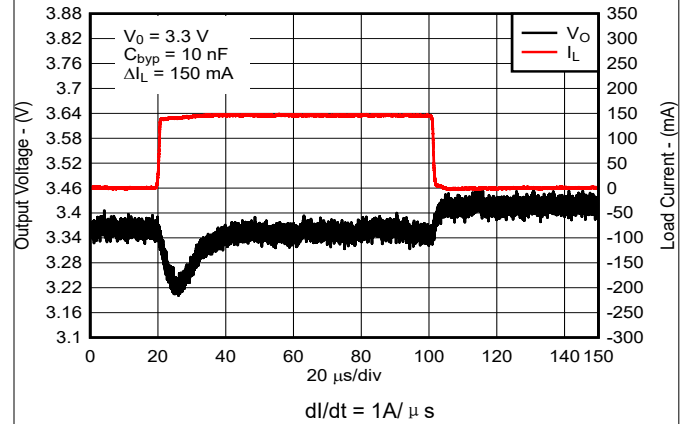


图 5-38. Load Transient (New Chip)

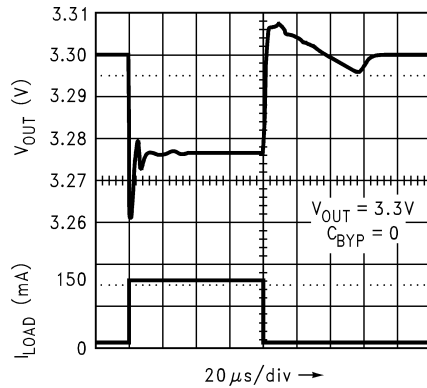


图 5-39. Load Transient Response (Legacy Chip)

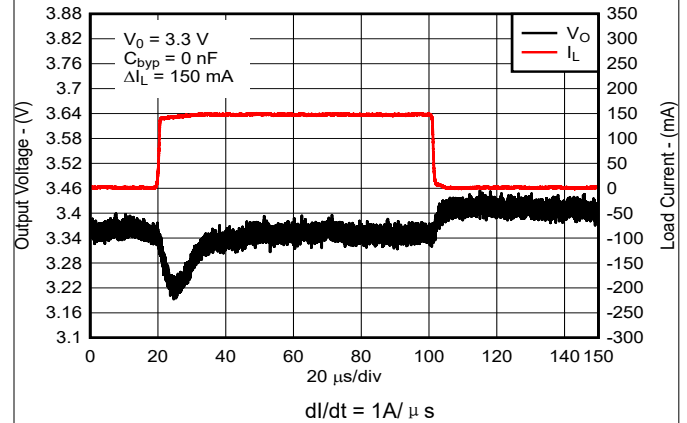


图 5-40. Load Transient Response (New Chip)

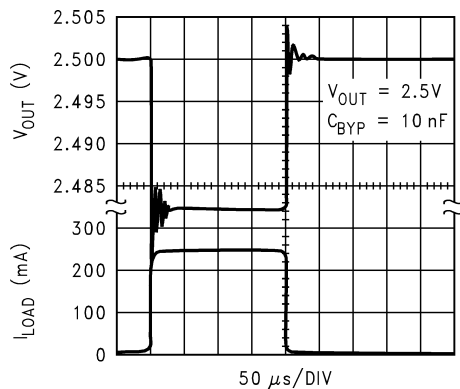


图 5-41. Load Transient Response (Legacy Chip)

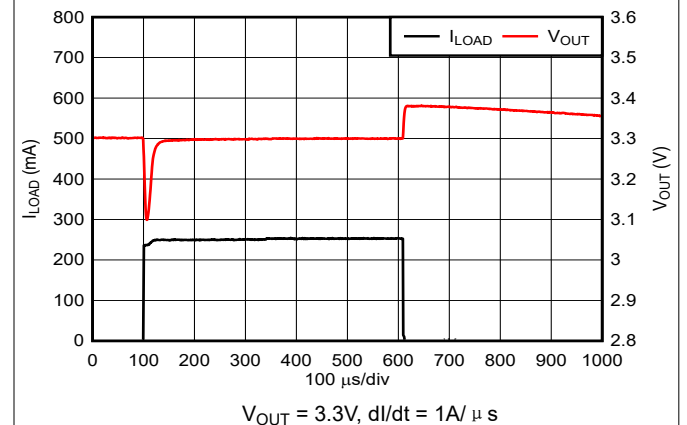


图 5-42. Load Transient Response (New Chip)

5.6 Typical Characteristics (continued)

$C_{IN} = 1\mu F$, $C_{OUT} = 4.7\mu F$, $V_{IN} = V_{OUT(NOM)} + 1V$, $T_A = 25^\circ C$, and ON/OFF pin is tied to the IN pin (unless otherwise noted)

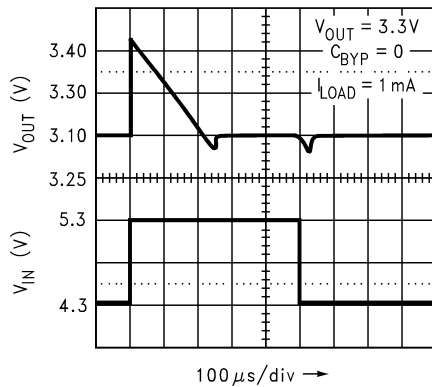


图 5-43. Line Transient Response (Legacy Chip)

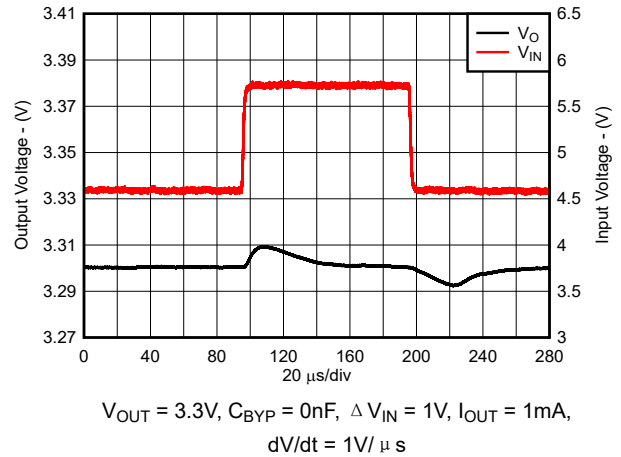


图 5-44. Line Transient Response (New Chip)

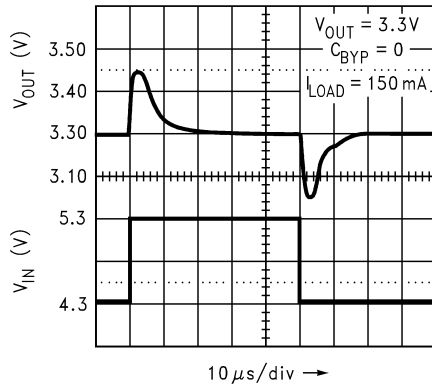


图 5-45. Line Transient Response (Legacy Chip)

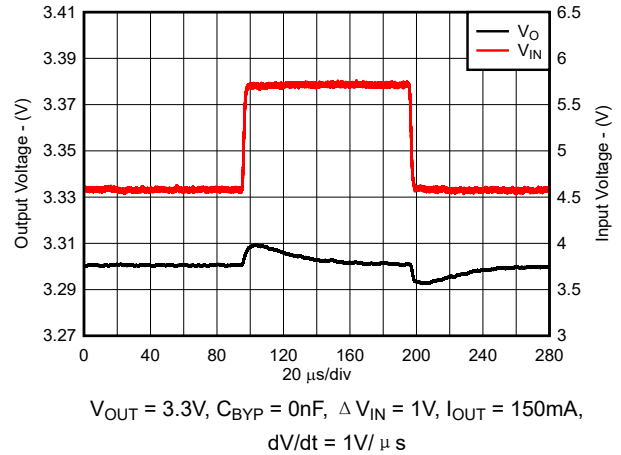


图 5-46. Line Transient Response (New Chip)

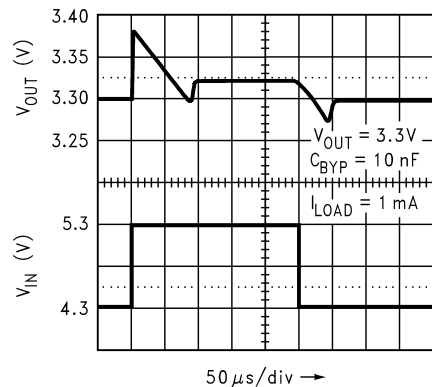


图 5-47. Line Transient Response (Legacy Chip)

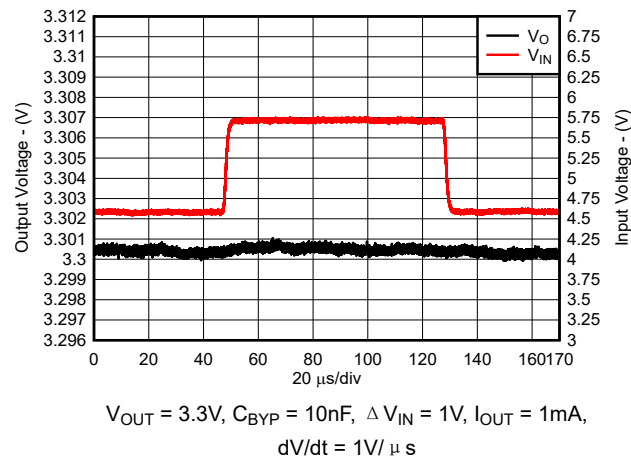


图 5-48. Line Transient Response (New Chip)

5.6 Typical Characteristics (continued)

$C_{IN} = 1\mu F$, $C_{OUT} = 4.7\mu F$, $V_{IN} = V_{OUT(NOM)} + 1V$, $T_A = 25^\circ C$, and ON/OFF pin is tied to the IN pin (unless otherwise noted)

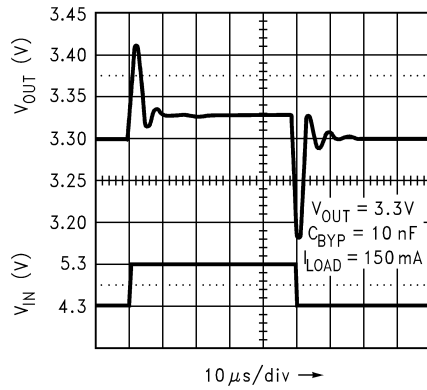


图 5-49. Line Transient Response (Legacy Chip)

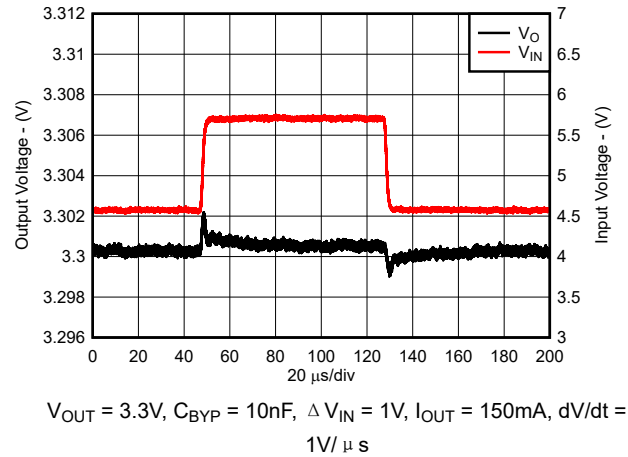


图 5-50. Line Transient Response (New Chip)

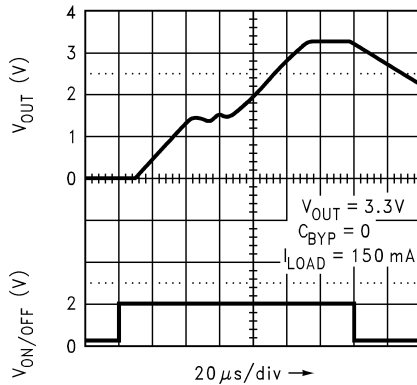


图 5-51. Turn-On Time (Legacy Chip)

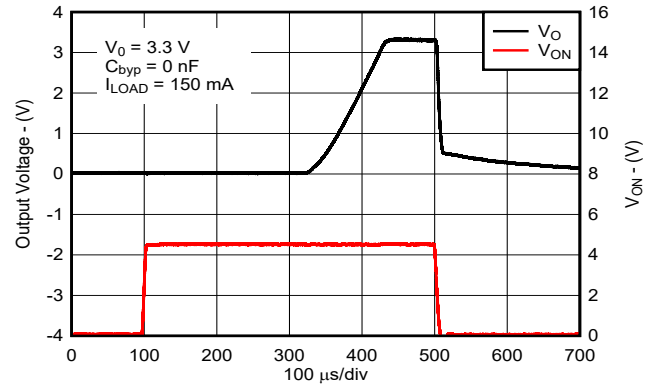


图 5-52. Turn-On Time (New Chip)

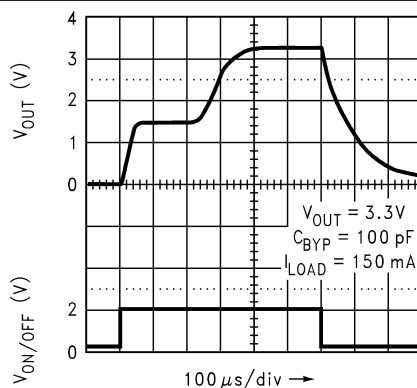


图 5-53. Turn-On Time (Legacy Chip)

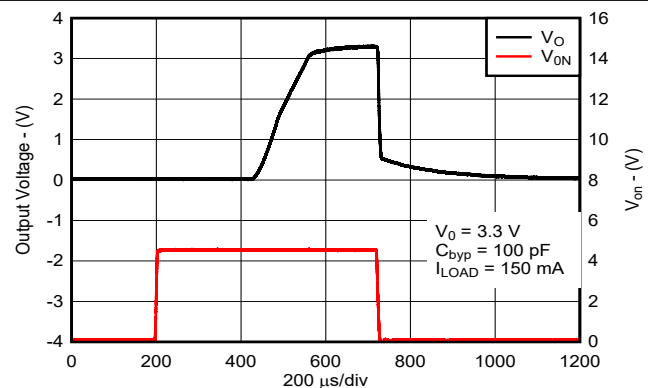


图 5-54. Turn-On Time (New Chip)

5.6 Typical Characteristics (continued)

$C_{IN} = 1\mu F$, $C_{OUT} = 4.7\mu F$, $V_{IN} = V_{OUT(NOM)} + 1V$, $T_A = 25^\circ C$, and ON/OFF pin is tied to the IN pin (unless otherwise noted)

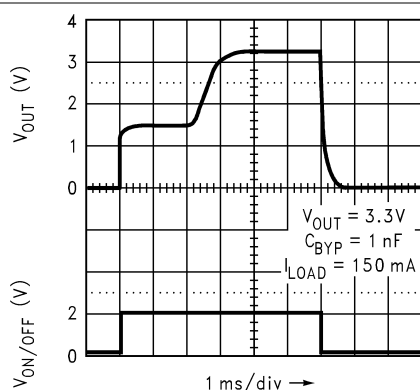


图 5-55. Turn-On Time (Legacy Chip)

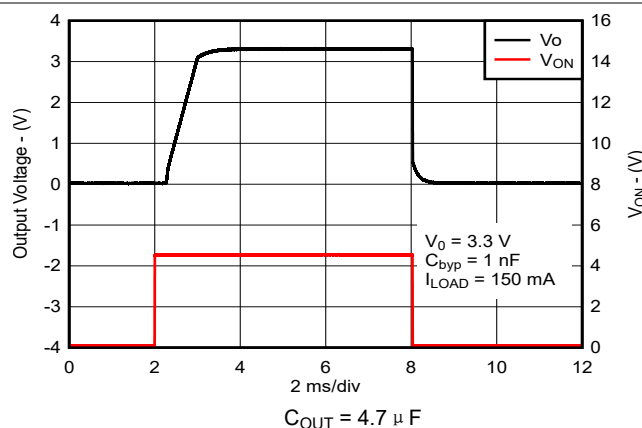


图 5-56. Turn-On Time (New Chip)

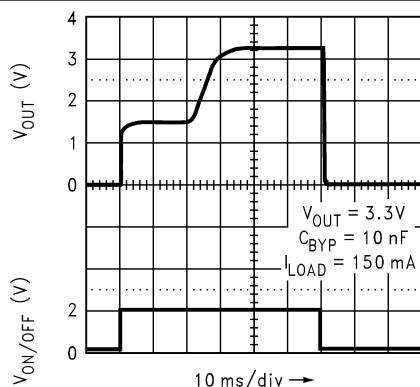


图 5-57. Turn-On Time (Legacy Chip)

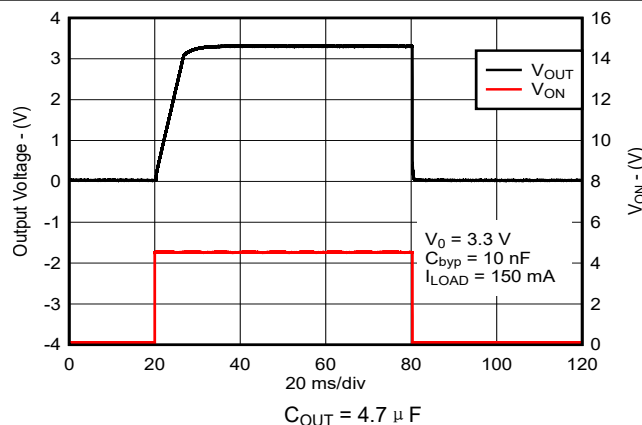


图 5-58. Turn-On Time (New Chip)

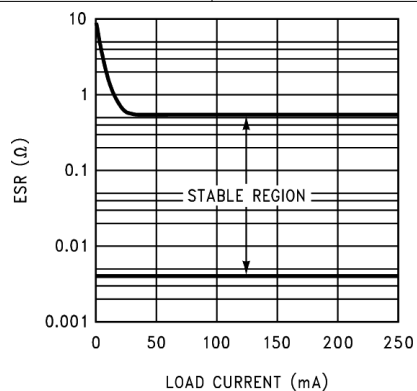


图 5-59. Stable ESR Range vs Load Current (Legacy Chip)

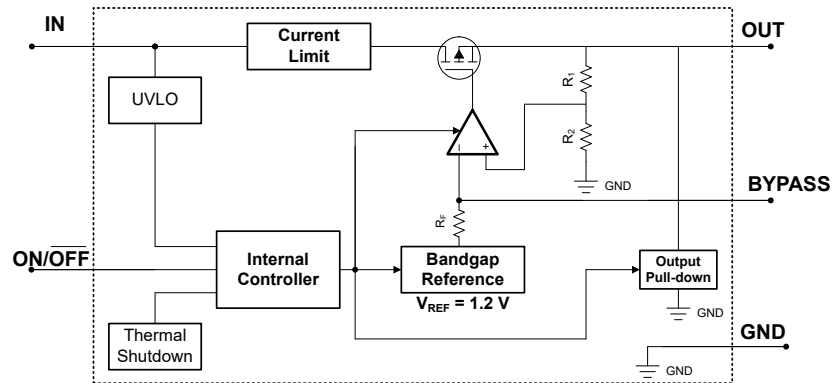
6 Detailed Description

6.1 Overview

The LP2991 is a fixed-output, low-noise, high PSRR, low-dropout regulator that offers exceptional, cost-effective performance for both portable and nonportable applications. The LP2991 has an output tolerance of 1% across line, load, and temperature variation (for the new chip) and is capable of delivering 250 mA of continuous load current.

This device features integrated overcurrent protection, thermal shutdown, output enable, and internal output pulldown and has a built-in soft-start mechanism for controlled inrush current. This device delivers excellent line and load transient performance. The operating ambient temperature range of the device is -40°C to 125°C .

6.2 Functional Block Diagram



6.3 Feature Description

6.3.1 Output Enable

The ON/ $\overline{\text{OFF}}$ pin for the device is an active-high pin. The output voltage is enabled when the voltage of the ON/ $\overline{\text{OFF}}$ pin is greater than the high-level input voltage of the ON/ $\overline{\text{OFF}}$ pin and disabled with the ON/ $\overline{\text{OFF}}$ pin voltage is less than the low-level input voltage of the ON/ $\overline{\text{OFF}}$ pin. If independent control of the output voltage is not needed, connect the ON/ $\overline{\text{OFF}}$ pin to the input of the device.

The device has an internal pulldown circuit that activates when the device is disabled by pulling the ON/ $\overline{\text{OFF}}$ pin voltage lower than the low-level input voltage of the ON/ $\overline{\text{OFF}}$ pin, to actively discharge the output voltage.

6.3.2 Dropout Voltage

Dropout voltage (V_{DO}) is defined as the input voltage minus the output voltage ($V_{\text{IN}} - V_{\text{OUT}}$) at the rated output current (I_{RATED}), where the pass transistor is fully on. I_{RATED} is the maximum I_{OUT} listed in the [Recommended Operating Conditions](#) table. The pass transistor is in the ohmic or triode region of operation, and acts as a switch. The dropout voltage indirectly specifies a minimum input voltage greater than the nominal programmed output voltage at which the output voltage is expected to stay in regulation. If the input voltage falls to less than the nominal output regulation, then the output voltage falls as well.

For a CMOS regulator, the dropout voltage is determined by the drain-source on-state resistance ($R_{DS(ON)}$) of the pass transistor. Therefore, if the linear regulator operates at less than the rated current, the dropout voltage for that current scales accordingly. The following equation calculates the $R_{DS(ON)}$ of the device.

$$R_{DS(ON)} = \frac{V_{DO}}{I_{RATED}} \quad (1)$$

6.3.3 Current Limit

6.3.3.1 Current Limit (Legacy Chip)

The internal current-limit circuit protects the LDO against high-current faults or shorting events. The LDO is not designed to operate in a steady-state current limit. During a current-limit event, the LDO sources constant current. Therefore, the output voltage falls when the output impedance decreases. If current limit occurs and the resulting output voltage is low, excessive power is potentially dissipated across the LDO, resulting in a thermal shutdown of the output. The LP2992 features a foldback current limit that allows a high peak current when $V_{OUT} > 0.5V$. The device then reduces the maximum output current when V_{OUT} is forced to ground.

6.3.3.2 Current Limit (New Chip)

The device has an internal current limit circuit that protects the regulator during transient high-load current faults or shorting events. The current limit is a brick-wall scheme. In a high-load current fault, the brick-wall scheme limits the output current to the current limit (I_{CL}). I_{CL} is listed in the [Electrical Characteristics](#) table.

The output voltage is not regulated when the device is in current limit. When a current limit event occurs, the device begins to heat up because of the increase in power dissipation. When the device is in brick-wall current limit, the pass transistor dissipates power $[(V_{IN} - V_{OUT}) \times I_{CL}]$. If thermal shutdown is triggered, the device turns off. After the device cools down, the internal thermal shutdown circuit turns the device back on. If the output current fault condition continues, the device cycles between current limit and thermal shutdown. For more information on current limits, see the [Know Your Limits](#) application note.

图 6-1 shows a diagram of the current limit.

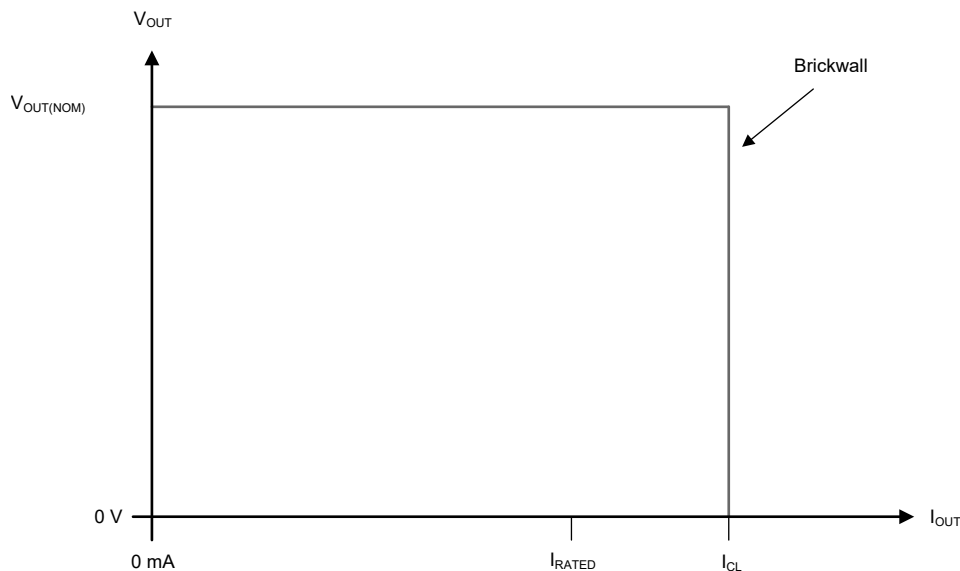


图 6-1. Current Limit

6.3.4 Undervoltage Lockout (UVLO)

The device has an independent undervoltage lockout (UVLO) circuit that monitors the input voltage, allowing a controlled and consistent turn on and off of the output voltage. To prevent the device from turning off if the input drops during turn on, the UVLO has hysteresis as specified in the [Electrical Characteristics](#) table.

6.3.5 Output Pulldown

The new chip has an output pulldown circuit. The output pulldown activates in the following conditions:

- When the device is disabled ($V_{ON/OFF} < V_{ON/OFF(LOW)}$)
- If $1.0V < V_{IN} < V_{UVLO}$

Do not rely on the output pulldown circuit for discharging a large amount of output capacitance after the input supply has collapsed because reverse current can flow from the output to the input. This reverse current flow can cause damage to the device. See the [Reverse Current](#) section for more details.

6.3.6 Thermal Shutdown

The device contains a thermal shutdown protection circuit to disable the device when the junction temperature (T_J) of the pass transistor rises to $T_{SD(shutdown)}$ (typical). Thermal shutdown hysteresis resets (turns on) the device when the temperature falls to $T_{SD(reset)}$ (typical).

The thermal time-constant of the semiconductor die is fairly short, thus the device can cycle on and off when thermal shutdown is reached until power dissipation is reduced. Power dissipation during start up can be high from large $V_{IN} - V_{OUT}$ voltage drops across the device or from high inrush currents charging large output capacitors. Under some conditions, the thermal shutdown protection disables the device before start up completes.

For reliable operation, limit the junction temperature to the maximum listed in the [Recommended Operating Conditions](#) table. Operation above this maximum temperature causes the device to exceed operational specifications. Although the internal protection circuitry of the device is designed to protect against thermal overall conditions, this circuitry is not intended to replace proper heat sinking. Continuously running the device into thermal shutdown or above the maximum recommended junction temperature reduces long-term reliability.

6.4 Device Functional Modes

表 6-1 shows the conditions that lead to the different modes of operation. See the [Electrical Characteristics](#) table for parameter values.

表 6-1. Device Functional Mode Comparison

OPERATING MODE	PARAMETER			
	V_{IN}	$V_{ON/OFF}$	I_{OUT}	T_J
Normal operation	$V_{IN} > V_{OUT(nom)} + V_{DO}$ and $V_{IN} > V_{IN(min)}$	$V_{ON/OFF} > V_{ON/OFF(HI)}$	$I_{OUT} < I_{OUT(max)}$	$T_J < T_{SD(shutdown)}$
Dropout operation	$V_{IN(min)} < V_{IN} < V_{OUT(nom)} + V_{DO}$	$V_{ON/OFF} > V_{ON/OFF(HI)}$	$I_{OUT} < I_{OUT(max)}$	$T_J < T_{SD(shutdown)}$
Disabled (any true condition disables the device)	$V_{IN} < V_{UVLO}$	$V_{ON/OFF} < V_{ON/OFF(LOW)}$	Not applicable	$T_J > T_{SD(shutdown)}$

6.4.1 Normal Operation

The device regulates to the nominal output voltage when the following conditions are met:

- The input voltage is greater than the nominal output voltage plus the dropout voltage ($V_{OUT(nom)} + V_{DO}$)
- The output current is less than the current limit ($I_{OUT} < I_{CL}$)
- The device junction temperature is less than the thermal shutdown temperature ($T_J < T_{SD}$)
- The ON/OFF voltage has previously exceeded the ON/OFF rising threshold voltage and has not yet decreased to less than the enable falling threshold

6.4.2 Dropout Operation

If the input voltage is lower than the nominal output voltage plus the specified dropout voltage, but all other conditions are met for normal operation, the device operates in dropout mode. In this mode, the output voltage tracks the input voltage. During this mode, the transient performance of the device becomes significantly degraded because the pass transistor is in the ohmic or triode region, and acts as a switch. Line or load transients in dropout can result in large output-voltage deviations.

When the device is in a steady dropout state (defined as when the device is in dropout, $V_{IN} < V_{OUT(NOM)} + V_{DO}$, directly after being in a normal regulation state, but *not* during start up), the pass transistor is driven into the ohmic or triode region. When the input voltage returns to a value greater than or equal to the nominal output voltage plus the dropout voltage ($V_{OUT(NOM)} + V_{DO}$), the output voltage can overshoot for a short period of time while the device pulls the pass transistor back into the linear region.

6.4.3 Disabled

The output of the device can be shutdown by forcing the voltage of the ON/OFF pin to less than the maximum ON/OFF pin low-level input voltage (see the [Electrical Characteristics](#) table). When disabled, the pass transistor is turned off, internal circuits are shutdown, and the output voltage is actively discharged to ground by an internal discharge circuit from the output to ground.

7 Application and Implementation

备注

以下应用部分中的信息不属于 TI 器件规格的范围，TI 不担保其准确性和完整性。TI 的客户应负责确定器件是否适用于其应用。客户应验证并测试其设计，以确保系统功能。

7.1 Application Information

7.1.1 Estimating Junction Temperature

The JEDEC standard now recommends the use of psi (Ψ) thermal metrics to estimate the junction temperatures of the linear regulator when in-circuit on a typical PCB board application. These metrics are not thermal resistance parameters and instead offer a practical and relative way to estimate junction temperature. These psi metrics are determined to be significantly independent of the copper area available for heat-spreading. The [Thermal Information](#) lists the primary thermal metrics, which are the junction-to-top characterization parameter (Ψ_{JT}) and junction-to-board characterization parameter (Ψ_{JB}). These parameters provide two methods for calculating the junction temperature (T_J), as described in the following equations. Use the junction-to-top characterization parameter (Ψ_{JT}) with the temperature at the center-top of device package (T_T) to calculate the junction temperature. Use the junction-to-board characterization parameter (Ψ_{JB}) with the PCB surface temperature 1mm from the device package (T_B) to calculate the junction temperature.

$$T_J = T_T + \Psi_{JT} \times P_D \quad (2)$$

where:

- P_D is the dissipated power
- T_T is the temperature at the center-top of the device package

$$T_J = T_B + \Psi_{JB} \times P_D \quad (3)$$

where:

- T_B is the PCB surface temperature measured 1mm from the device package and centered on the package edge

For detailed information on the thermal metrics and how to use them, see the [Semiconductor and IC Package Thermal Metrics](#) application note.

7.1.2 Input and Output Capacitor Requirements

Although an input capacitor is not required for stability, good analog design practice is to connect a capacitor from IN to GND. This capacitor counteracts reactive input sources and improves transient response, input ripple, and PSRR. Use an input capacitor if the source impedance is more than $0.5\ \Omega$. A higher value capacitor can be necessary if large, fast rise-time load or line transients are anticipated or if the device is located several inches from the input power source.

Dynamic performance of the device is improved with the use of an output capacitor. Use an output capacitor within the range specified in the [Recommended Operating Conditions](#) table for stability.

7.1.3 Noise Bypass Capacitor (C_{BYPASS})

The LP2992 allows for low-noise performance with the use of a bypass capacitor that is connected to the internal band-gap reference with the BYPASS pin. This high-impedance band-gap circuitry is biased in the microampere range and, thus, cannot be loaded significantly, otherwise, the output (and, correspondingly, the output of the regulator) changes. Thus, for best output accuracy, dc leakage current through C_{BYPASS} must be minimized as much as possible and must never exceed 100nA. The C_{BYPASS} capacitor also impacts the start-up behavior of the regulator. Inrush current and start-up time increase with larger bypass capacitor values.

Use a 10nF capacitor for C_{BYPASS} . Ceramic and film capacitors are good choices for this purpose.

7.1.4 Power Dissipation (P_D)

Circuit reliability requires consideration of the device power dissipation, location of the circuit on the printed circuit board (PCB), and correct sizing of the thermal plane. The PCB area around the regulator must have few or no other heat-generating devices that cause added thermal stress.

To first-order approximation, power dissipation in the regulator depends on the input-to-output voltage difference and load conditions. The following equation calculates power dissipation (P_D).

$$P_D = (V_{\text{IN}} - V_{\text{OUT}}) \times I_{\text{OUT}} \quad (4)$$

备注

Power dissipation can be minimized, and therefore greater efficiency can be achieved, by correct selection of the system voltage rails. For the lowest power dissipation use the minimum input voltage required for correct output regulation.

For devices with a thermal pad, the primary heat conduction path for the device package is through the thermal pad to the PCB. Solder the thermal pad to a copper pad area under the device. This pad area must contain an array of plated vias that conduct heat to additional copper planes for increased heat dissipation.

The maximum power dissipation determines the maximum allowable ambient temperature (T_A) for the device. According to the following equation, power dissipation and junction temperature are most often related by the junction-to-ambient thermal resistance ($R_{\theta JA}$) of the combined PCB and device package and the temperature of the ambient air (T_A).

$$T_J = T_A + (R_{\theta JA} \times P_D) \quad (5)$$

Thermal resistance ($R_{\theta JA}$) is highly dependent on the heat-spreading capability built into the particular PCB design, and therefore varies according to the total copper area, copper weight, and location of the planes. The junction-to-ambient thermal resistance listed in the [Thermal Information](#) table is determined by the JEDEC standard PCB and copper-spreading area, and is used as a relative measure of package thermal performance.

7.1.5 Recommended Capacitor Types

This section describes the recommended capacitors for both the new chip and the legacy chip.

7.1.5.1 Recommended Capacitors (Legacy Chip)

The LP2992 is designed specifically to work with ceramic output capacitors, using circuitry that allows the regulator to be stable across the entire range of output current with an output capacitor whose ESR is as low as $5\text{m}\Omega$. Tantalum or film capacitors are available for use at the output, but these capacitors are not as attractive for size and cost reasons.

Make sure the output capacitor meets the requirement for minimum amount of capacitance and also have an ESR value within the stable range. Curves are provided that show the stable ESR range as a function of load current (see [图 5-59](#)).

Make sure the output capacitor maintains the ESR within the stable region over the full operating temperature range of the application to provide stability.

The legacy chip version of the LP2992 requires a minimum of $4.7\mu\text{F}$ on the output (increase output capacitor size without limit). Remember to take capacitor tolerance and variation with temperature into consideration when selecting an output capacitor so that the minimum required amount of output capacitance is provided over the full operating temperature range. Ceramic capacitors potentially exhibit large changes in capacitance with temperature.

Do not locate the output capacitor more than 1cm from the output pin. Make sure the output capacitor returns to a clean analog ground.

7.1.5.1.1 Tantalum Capacitors (Legacy Chip)

Tantalum capacitors are less desirable than ceramics for use as output capacitors because these components are more expensive when comparing equivalent capacitance and voltage ratings in the 1μF to 4.7μF range.

Another important consideration is that tantalum capacitors have higher ESR values than equivalent size ceramics. This condition means that although finding a Tantalum capacitor with an ESR value within the stable range is possible, the capacitor is larger in capacitance (which means bigger and more costly) than a ceramic capacitor with the same ESR value.

The ESR of a typical tantalum increases approximately 2:1 as the temperature goes from 25°C down to -40°C, so allow for some guard band.

7.1.5.2 Recommended Capacitors (New Chip)

The device is designed to be stable using low equivalent series resistance (ESR) ceramic capacitors at the input and output. Multilayer ceramic capacitors have become the industry standard for these types of applications and are recommended, but must be used with good judgment. Ceramic capacitors that employ X7R-, X5R-, and C0G-rated dielectric materials provide relatively good capacitive stability across temperature, whereas the use of Y5V-rated capacitors is discouraged because of large variations in capacitance.

Regardless of the ceramic capacitor type selected, the effective capacitance varies with operating voltage and temperature. Generally, expect the effective capacitance to decrease by as much as 50%. The input and output capacitors listed in the [Recommended Operating Conditions](#) account for an effective capacitance of approximately 50% of the nominal value.

7.1.6 Reverse Current

Excessive reverse current can damage this device. Reverse current flows through the intrinsic body diode of the pass transistor instead of the normal conducting channel. At high magnitudes, this current flow degrades the long-term reliability of the device.

Conditions where reverse current can occur are outlined in this section, all of which can exceed the absolute maximum rating of $V_{OUT} \leq V_{IN} + 0.3 \text{ V}$.

- If the device has a large C_{OUT} and the input supply collapses with little or no load current
- The output is biased when the input supply is not established
- The output is biased above the input supply

If reverse current flow is expected in the application, use external protection to protect the device. Reverse current is not limited in the device, so external limiting is required if extended reverse voltage operation is anticipated.

图 7-1 shows one approach for protecting the device.

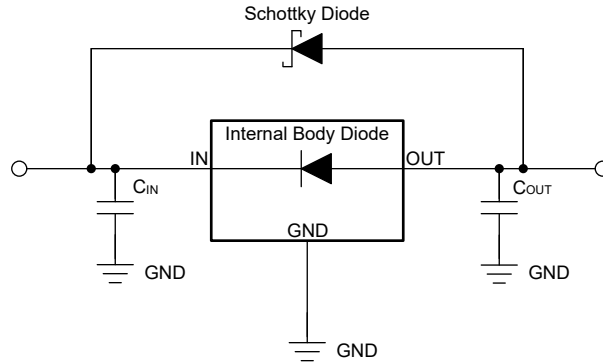


图 7-1. Example Circuit for Reverse Current Protection Using a Schottky Diode

7.2 Typical Application

图 7-2 shows the standard usage of the LP2992 as a low-dropout regulator.

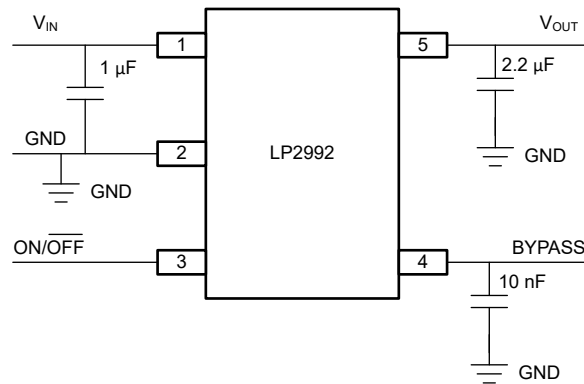


图 7-2. LP2992 Typical Application

7.2.1 Design Requirements

Minimum C_{OUT} value for stability (can be increased without limit for improved stability and transient response)

ON/OFF must be actively terminated. Connect to V_{IN} if shutdown feature is not used.

Optional BYPASS capacitor for low-noise operation.

7.2.2 Detailed Design Procedure

7.2.2.1 ON/OFF Operation

The LP2992 allows for a shutdown mode using the ON/OFF pin. Driving the pin LOW ($\leq 0.4V$) turns the device OFF; conversely, a HIGH ($\geq 1.2V$) turns the device ON. If the shutdown feature is not used, connect ON/OFF to the input so that the regulator is on at all times. For proper operation, do not leave ON/OFF unconnected.

7.2.3 Application Curves

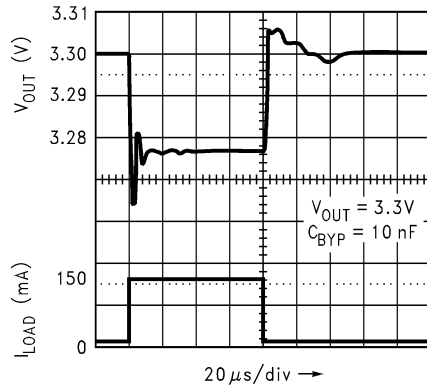


图 7-3. Load Transient Response for Legacy Chip

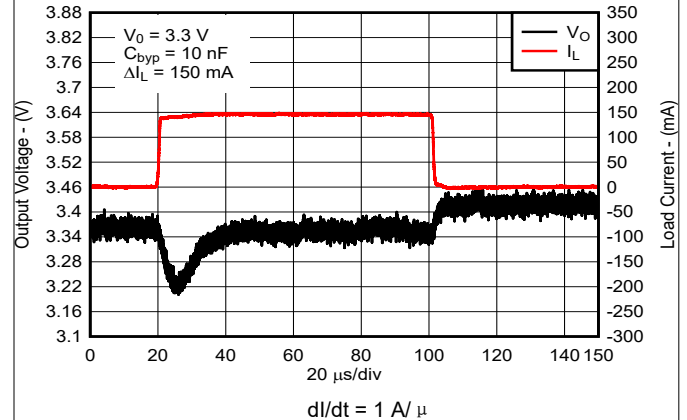


图 7-4. Load Transient for New Chip

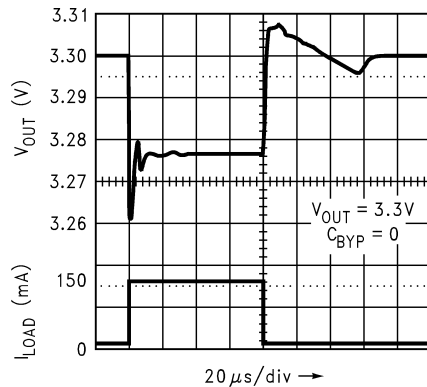


图 7-5. Load Transient Response for Legacy Chip

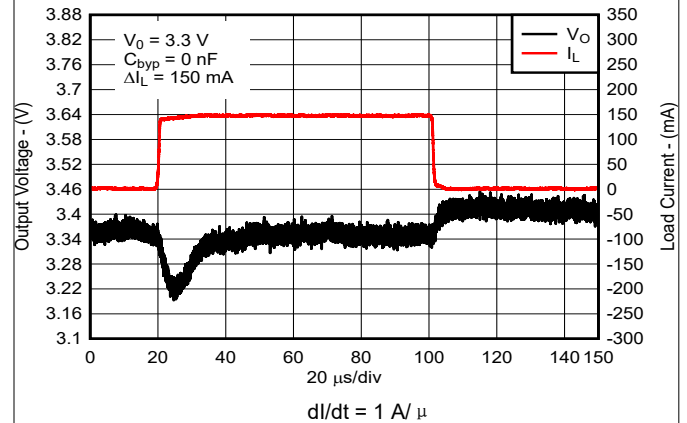


图 7-6. Load Transient Response for New Chip

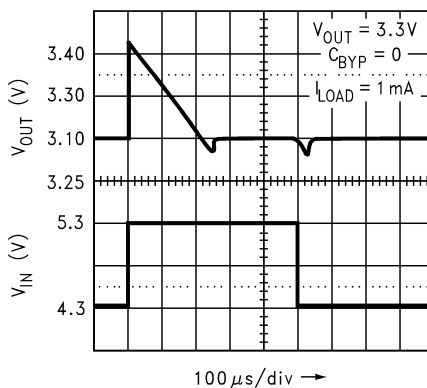


图 7-7. Line Transient Response for Legacy Chip

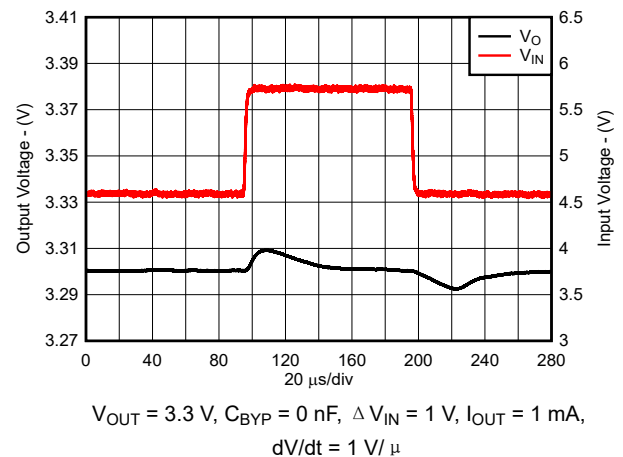


图 7-8. Line Transient Response for New Chip

7.2.3 Application Curves (continued)

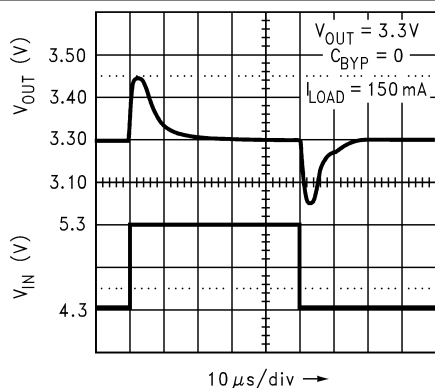


图 7-9. Line Transient Response for Legacy Chip

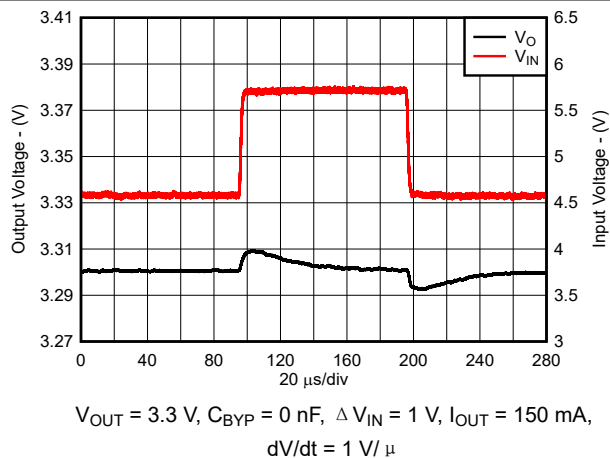


图 7-10. Line Transient Response for New Chip

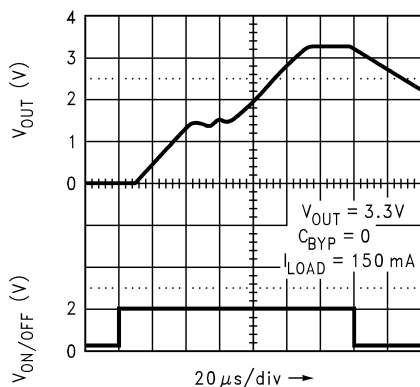


图 7-11. Turn-on Time for Legacy Chip

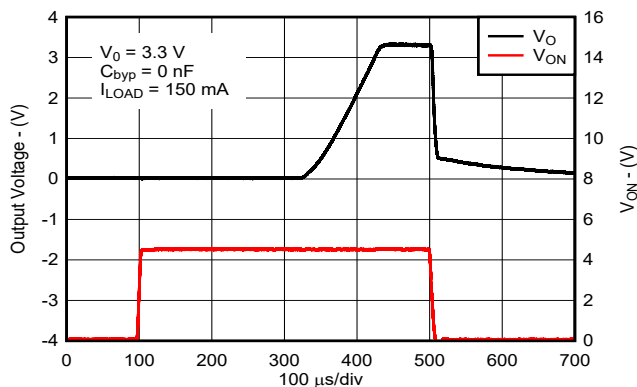


图 7-12. Turn-on Time for New Chip

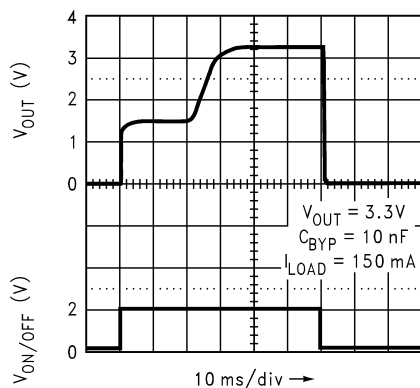


图 7-13. Turn-on Time for Legacy Chip

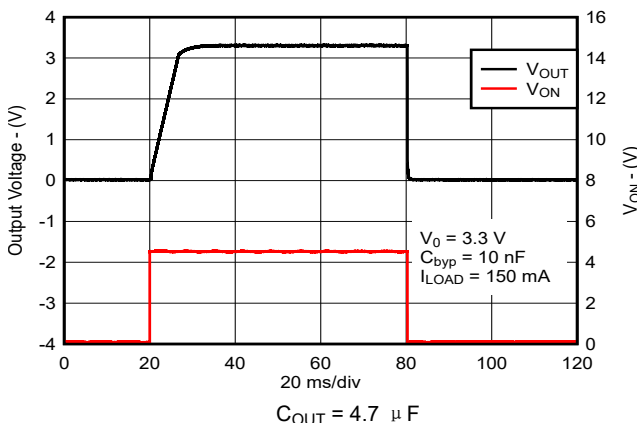


图 7-14. Turn-on Time for New Chip

7.3 Power Supply Recommendations

A power supply can be used at the input voltage within the ranges given in the [Recommended Operating Conditions](#) table. Use bypass capacitors as described in the [Layout Guidelines](#) section.

7.4 Layout

7.4.1 Layout Guidelines

- Bypass the input pin to ground with a bypass capacitor.
- The optimum placement of the bypass capacitor is closest to the V_{IN} of the device and GND of the system. Care must be taken to minimize the loop area formed by the bypass capacitor connection, the V_{IN} pin, and the GND pin of the system.
- For operation at full-rated load, use wide trace lengths to eliminate IR drop and heat dissipation.

7.4.2 Layout Examples

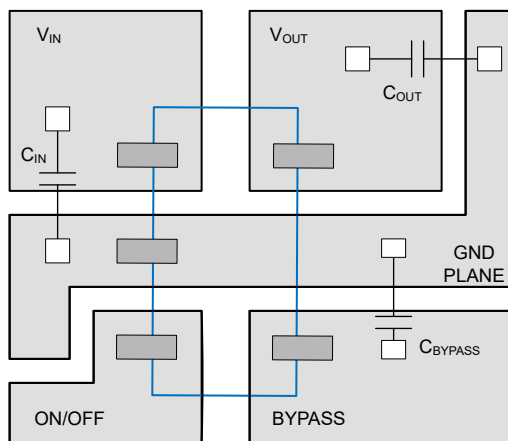


图 7-15. Layout Diagram

8 Device and Documentation Support

8.1 Device Nomenclature

表 8-1. Available Options

PRODUCT ⁽¹⁾	V _{OUT}
LP2992vw ^x xy-z.z/NOPB	v is the accuracy specification for the legacy chip (A or blank). See the Electrical Characteristics for more information. This character is insignificant for the new chip. w is the operating temperature range (I = -40°C to +125°C). xx is the package designator. y is the reel designator size. See the Package Addendum for more information on package quantity. z.z is the nominal output voltage (for example, 3.3 = 3.3V; 5.0 = 5.0V). /NOPB indicates material construction that does not use Lead (Pb). This device ships with the legacy chip (CSO: DLN or GF8) or the new chip (CSO: RFB), which uses the latest manufacturing flow. The reel packaging label provides CSO information to distinguish which chip is used. Device performance for new and legacy chips is denoted throughout the document.

(1) For the most current package and ordering information, see the Package Option Addendum at the end of this document, or visit the device product folder at www.ti.com.

8.2 Documentation Support

8.2.1 Related Documentation

For related documentation see the following:

- Texas Instruments, [AN-1187 Leadless Leadframe Package \(LLP\)](#), application note
- Texas Instruments, [Semiconductor and IC Package Thermal Metrics](#), application note
- Texas Instruments, [Using New Thermal Metrics](#), application note
- Texas Instruments, [Thermal Characteristics of Linear and Logic Packages Using JEDEC PCB Designs](#), application note

8.3 Receiving Notification of Documentation Updates

To receive notification of documentation updates, navigate to the device product folder on ti.com. In the upper right corner, click on *Alert me* to register and receive a weekly digest of any product information that has changed. For change details, review the revision history included in any revised document.

8.4 支持资源

TI E2E™ 中文支持论坛是工程师的重要参考资料，可直接从专家处获得快速、经过验证的解答和设计帮助。搜索现有解答或提出自己的问题，获得所需的快速设计帮助。

链接的内容由各个贡献者“按原样”提供。这些内容并不构成 TI 技术规范，并且不一定反映 TI 的观点；请参阅 TI 的[使用条款](#)。

8.5 Trademarks

TI E2E™ is a trademark of Texas Instruments.

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8.6 静电放电警告



静电放电 (ESD) 会损坏这个集成电路。德州仪器 (TI) 建议通过适当的预防措施处理所有集成电路。如果不遵守正确的处理和安装程序，可能会损坏集成电路。

ESD 的损坏小至导致微小的性能降级，大至整个器件故障。精密的集成电路可能更容易受到损坏，这是因为非常细微的参数更改都可能会导致器件与其发布的规格不相符。

8.7 术语表

TI 术语表

本术语表列出并解释了术语、首字母缩略词和定义。

9 Revision History

注：以前版本的页码可能与当前版本的页码不同

Changes from Revision K (December 2023) to Revision L (February 2025)	Page
• 更新了整个文档中的表格、图和交叉参考的编号格式.....	1
• Changed V_{IN} pin to IN and V_{OUT} pin to OUT in <i>Pin Configuration and Functions</i> section.....	3
• Added ESR range for output capacitor.....	4
• Added <i>Stable ESR Range vs Load Current for Legacy Chip</i> curve.....	9
• Changed V_{IN} pin to IN and V_{OUT} pin to OUT in <i>Functional Block Diagram</i>	19
• Added <i>Recommended Capacitors (Legacy Chip)</i> section.....	24
• Added <i>Tantalum Capacitors (Legacy Chip)</i> section.....	25
• Added <i>Recommended Capacitors (New Chip)</i> section.....	25

Changes from Revision J (January 2017) to Revision K (December 2023)	Page
• 更改了整个文档以与当前系列格式保持一致.....	1
• 向文档添加了 M3 器件.....	1
• 更新了整个文档中的表格、图和交叉参考的编号格式.....	1
• Updated Absolute Maximum Ratings, Recommended Operating Conditions, Electrical Characteristics and Thermal Information for M3-suffix(new chip).....	6
• Changed <i>Current Limit</i> section.....	20
• Added <i>Output Pulldown</i> section.....	21
• Added <i>Device Nomenclature</i> section.....	30

10 Mechanical, Packaging, and Orderable Information

The following pages include mechanical, packaging, and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.

PACKAGING INFORMATION

Orderable part number	Status (1)	Material type (2)	Package Pins	Package qty Carrier	RoHS (3)	Lead finish/ Ball material (4)	MSL rating/ Peak reflow (5)	Op temp (°C)	Part marking (6)
LP2992AILD-1.5/NO.A	Active	Production	WSO (NGD) 6	1000 SMALL T&R	Yes	SN	Level-3-260C-168 HR	-40 to 125	L011A
LP2992AILD-1.5/NOPB	Active	Production	WSO (NGD) 6	1000 SMALL T&R	Yes	SN	Level-3-260C-168 HR	-40 to 125	L011A
LP2992AILD-1.8/NO.A	Active	Production	WSO (NGD) 6	1000 SMALL T&R	Yes	SN	Level-3-260C-168 HR	-40 to 125	L012A
LP2992AILD-1.8/NOPB	Active	Production	WSO (NGD) 6	1000 SMALL T&R	Yes	NIPDAU SN	Level-3-260C-168 HR	-40 to 125	L012A
LP2992AILD-3.3/NO.A	Active	Production	WSO (NGD) 6	1000 SMALL T&R	Yes	SN	Level-3-260C-168 HR	-40 to 125	L014A
LP2992AILD-3.3/NOPB	Active	Production	WSO (NGD) 6	1000 SMALL T&R	Yes	NIPDAU SN	Level-3-260C-168 HR	-40 to 125	L014A
LP2992AILD-5.0/NO.A	Active	Production	WSO (NGD) 6	1000 SMALL T&R	Yes	SN	Level-3-260C-168 HR	-40 to 125	L015A
LP2992AILD-5.0/NOPB	Active	Production	WSO (NGD) 6	1000 SMALL T&R	Yes	NIPDAU SN	Level-3-260C-168 HR	-40 to 125	L015A
LP2992AILD-3.3/NO.A	Active	Production	WSO (NGD) 6	4500 LARGE T&R	Yes	SN	Level-3-260C-168 HR	-40 to 125	L014A
LP2992AILD-3.3/NOPB	Active	Production	WSO (NGD) 6	4500 LARGE T&R	Yes	NIPDAU SN	Level-3-260C-168 HR	-40 to 125	L014A
LP2992AILD-5.0/NO.A	Active	Production	WSO (NGD) 6	4500 LARGE T&R	Yes	SN	Level-3-260C-168 HR	-40 to 125	L015A
LP2992AILD-5.0/NOPB	Active	Production	WSO (NGD) 6	4500 LARGE T&R	Yes	NIPDAU SN	Level-3-260C-168 HR	-40 to 125	L015A
LP2992AIM5-1.5/NO.A	Active	Production	SOT-23 (DBV) 5	1000 LARGE T&R	Yes	SN	Level-1-260C-UNLIM	-40 to 125	LFBA
LP2992AIM5-1.5/NOPB	Active	Production	SOT-23 (DBV) 5	1000 LARGE T&R	Yes	SN	Level-1-260C-UNLIM	-40 to 125	LFBA
LP2992AIM5-1.8/NO.A	Active	Production	SOT-23 (DBV) 5	3000 LARGE T&R	Yes	SN	Level-1-260C-UNLIM	-40 to 125	LFCA
LP2992AIM5-1.8/NOPB	Active	Production	SOT-23 (DBV) 5	3000 LARGE T&R	Yes	SN	Level-1-260C-UNLIM	-40 to 125	LFCA
LP2992AIM5-2.5/NO.A	Active	Production	SOT-23 (DBV) 5	3000 LARGE T&R	Yes	SN	Level-1-260C-UNLIM	-40 to 125	LFDA
LP2992AIM5-2.5/NOPB	Active	Production	SOT-23 (DBV) 5	3000 LARGE T&R	Yes	SN	Level-1-260C-UNLIM	-40 to 125	LFDA
LP2992AIM5-3.3/NO.A	Active	Production	SOT-23 (DBV) 5	3000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	LFEA
LP2992AIM5-3.3/NOPB	Active	Production	SOT-23 (DBV) 5	3000 LARGE T&R	Yes	NIPDAU SN	Level-1-260C-UNLIM	-40 to 125	LFEA
LP2992AIM5-5.0/NO.A	Active	Production	SOT-23 (DBV) 5	3000 LARGE T&R	Yes	SN	Level-1-260C-UNLIM	-40 to 125	LFFA
LP2992AIM5-5.0/NOPB	Active	Production	SOT-23 (DBV) 5	3000 LARGE T&R	Yes	SN	Level-1-260C-UNLIM	-40 to 125	LFFA
LP2992AIM5X-1.5/NO.A	Active	Production	SOT-23 (DBV) 5	3000 LARGE T&R	Yes	SN	Level-1-260C-UNLIM	-40 to 125	LFBA
LP2992AIM5X-1.5/NOPB	Active	Production	SOT-23 (DBV) 5	3000 LARGE T&R	Yes	SN	Level-1-260C-UNLIM	-40 to 125	LFBA
LP2992AIM5X-1.8/NO.A	Active	Production	SOT-23 (DBV) 5	3000 LARGE T&R	Yes	SN	Level-1-260C-UNLIM	-40 to 125	LFCA
LP2992AIM5X-1.8/NOPB	Active	Production	SOT-23 (DBV) 5	3000 LARGE T&R	Yes	SN	Level-1-260C-UNLIM	-40 to 125	LFCA
LP2992AIM5X-2.5/NO.A	Active	Production	SOT-23 (DBV) 5	3000 LARGE T&R	Yes	SN	Level-1-260C-UNLIM	-40 to 125	LFDA
LP2992AIM5X-2.5/NOPB	Active	Production	SOT-23 (DBV) 5	3000 LARGE T&R	Yes	SN	Level-1-260C-UNLIM	-40 to 125	LFDA
LP2992AIM5X-3.3/NO.A	Active	Production	SOT-23 (DBV) 5	3000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	LFEA

Orderable part number	Status (1)	Material type (2)	Package Pins	Package qty Carrier	RoHS (3)	Lead finish/ Ball material (4)	MSL rating/ Peak reflow (5)	Op temp (°C)	Part marking (6)
LP2992AIM5X-3.3/NO.B	Active	Production	SOT-23 (DBV) 5	3000 LARGE T&R	-	Call TI	Call TI	-40 to 125	
LP2992AIM5X-3.3/NOPB	Active	Production	SOT-23 (DBV) 5	3000 LARGE T&R	Yes	NIPDAU SN	Level-1-260C-UNLIM	-40 to 125	LFEA
LP2992AIM5X-5.0/NO.A	Active	Production	SOT-23 (DBV) 5	3000 LARGE T&R	Yes	SN	Level-1-260C-UNLIM	-40 to 125	LFFA
LP2992AIM5X-5.0/NOPB	Active	Production	SOT-23 (DBV) 5	3000 LARGE T&R	Yes	SN	Level-1-260C-UNLIM	-40 to 125	LFFA
LP2992ILD-1.8/NOPB	Active	Production	WSON (NGD) 6	1000 SMALL T&R	Yes	NIPDAU SN	Level-3-260C-168 HR	-40 to 125	L012A B
LP2992ILD-1.8/NOPB.A	Active	Production	WSON (NGD) 6	1000 SMALL T&R	Yes	SN	Level-3-260C-168 HR	-40 to 125	L012A B
LP2992ILD-1.8/NOPB.B	Active	Production	WSON (NGD) 6	1000 SMALL T&R	Yes	SN	Level-3-260C-168 HR	-40 to 125	L012A B
LP2992ILD-2.5/NOPB	Active	Production	WSON (NGD) 6	1000 SMALL T&R	Yes	SN	Level-3-260C-168 HR	-40 to 125	L013A B
LP2992ILD-2.5/NOPB.A	Active	Production	WSON (NGD) 6	1000 SMALL T&R	Yes	SN	Level-3-260C-168 HR	-40 to 125	L013A B
LP2992ILD-2.5/NOPB.B	Active	Production	WSON (NGD) 6	1000 SMALL T&R	Yes	SN	Level-3-260C-168 HR	-40 to 125	L013A B
LP2992ILD-3.3/NOPB	Active	Production	WSON (NGD) 6	1000 SMALL T&R	Yes	NIPDAU SN	Level-3-260C-168 HR	-40 to 125	L014A B
LP2992ILD-3.3/NOPB.A	Active	Production	WSON (NGD) 6	1000 SMALL T&R	Yes	SN	Level-3-260C-168 HR	-40 to 125	L014A B
LP2992ILD-3.3/NOPB.B	Active	Production	WSON (NGD) 6	1000 SMALL T&R	Yes	SN	Level-3-260C-168 HR	-40 to 125	L014A B
LP2992ILD-5.0/NOPB	Active	Production	WSON (NGD) 6	1000 SMALL T&R	Yes	NIPDAU SN	Level-3-260C-168 HR	-40 to 125	L015A B
LP2992ILD-5.0/NOPB.A	Active	Production	WSON (NGD) 6	1000 SMALL T&R	Yes	SN	Level-3-260C-168 HR	-40 to 125	L015A B
LP2992ILD-5.0/NOPB.B	Active	Production	WSON (NGD) 6	1000 SMALL T&R	Yes	SN	Level-3-260C-168 HR	-40 to 125	L015A B
LP2992ILD-1.5/NO.A	Active	Production	WSON (NGD) 6	4500 LARGE T&R	Yes	SN	Level-3-260C-168 HR	-40 to 125	L011A B
LP2992ILD-1.5/NOPB	Active	Production	WSON (NGD) 6	4500 LARGE T&R	Yes	NIPDAU SN	Level-3-260C-168 HR	-40 to 125	L011A B
LP2992ILD-3.3/NO.A	Active	Production	WSON (NGD) 6	4500 LARGE T&R	Yes	SN	Level-3-260C-168 HR	-40 to 125	L014A B

Orderable part number	Status (1)	Material type (2)	Package Pins	Package qty Carrier	RoHS (3)	Lead finish/ Ball material (4)	MSL rating/ Peak reflow (5)	Op temp (°C)	Part marking (6)
LP2992ILDX-3.3/NOPB	Active	Production	WSON (NGD) 6	4500 LARGE T&R	Yes	NIPDAU SN	Level-3-260C-168 HR	-40 to 125	L014A B
LP2992ILDX-5.0/NO.A	Active	Production	WSON (NGD) 6	4500 LARGE T&R	Yes	SN	Level-3-260C-168 HR	-40 to 125	L015A B
LP2992ILDX-5.0/NOPB	Active	Production	WSON (NGD) 6	4500 LARGE T&R	Yes	SN	Level-3-260C-168 HR	-40 to 125	L015A B
LP2992IM5-1.5/NOPB	Active	Production	SOT-23 (DBV) 5	1000 LARGE T&R	Yes	SN	Level-1-260C-UNLIM	-40 to 125	LFBB
LP2992IM5-1.5/NOPB.A	Active	Production	SOT-23 (DBV) 5	1000 LARGE T&R	Yes	SN	Level-1-260C-UNLIM	-40 to 125	LFBB
LP2992IM5-1.5/NOPB.B	Active	Production	SOT-23 (DBV) 5	1000 LARGE T&R	Yes	SN	Level-1-260C-UNLIM	-40 to 125	LFBB
LP2992IM5-1.8/NOPB	Active	Production	SOT-23 (DBV) 5	3000 LARGE T&R	Yes	SN	Level-1-260C-UNLIM	-40 to 125	LFCEB
LP2992IM5-1.8/NOPB.A	Active	Production	SOT-23 (DBV) 5	3000 LARGE T&R	Yes	SN	Level-1-260C-UNLIM	-40 to 125	LFCEB
LP2992IM5-2.5/NOPB	Active	Production	SOT-23 (DBV) 5	1000 SMALL T&R	Yes	SN	Level-1-260C-UNLIM	-40 to 125	LFDB
LP2992IM5-2.5/NOPB.A	Active	Production	SOT-23 (DBV) 5	1000 SMALL T&R	Yes	SN	Level-1-260C-UNLIM	-40 to 125	LFDB
LP2992IM5-2.5/NOPB.B	Active	Production	SOT-23 (DBV) 5	1000 SMALL T&R	Yes	SN	Level-1-260C-UNLIM	-40 to 125	LFDB
LP2992IM5-3.0/NOPB	Active	Production	SOT-23 (DBV) 5	1000 LARGE T&R	Yes	SN	Level-1-260C-UNLIM	-40 to 125	LF8B
LP2992IM5-3.0/NOPB.A	Active	Production	SOT-23 (DBV) 5	1000 LARGE T&R	Yes	SN	Level-1-260C-UNLIM	-40 to 125	LF8B
LP2992IM5-3.0/NOPB.B	Active	Production	SOT-23 (DBV) 5	1000 LARGE T&R	Yes	SN	Level-1-260C-UNLIM	-40 to 125	LF8B
LP2992IM5-3.3/NOPB	Active	Production	SOT-23 (DBV) 5	3000 LARGE T&R	Yes	NIPDAU SN	Level-1-260C-UNLIM	-40 to 125	LFEB
LP2992IM5-3.3/NOPB.A	Active	Production	SOT-23 (DBV) 5	3000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	LFEB
LP2992IM5-5.0/NOPB	Active	Production	SOT-23 (DBV) 5	3000 LARGE T&R	Yes	SN	Level-1-260C-UNLIM	-40 to 125	LFEB
LP2992IM5-5.0/NOPB.A	Active	Production	SOT-23 (DBV) 5	3000 LARGE T&R	Yes	SN	Level-1-260C-UNLIM	-40 to 125	LFEB
LP2992IM5X-1.5/NO.A	Active	Production	SOT-23 (DBV) 5	3000 LARGE T&R	Yes	SN	Level-1-260C-UNLIM	-40 to 125	LFBB
LP2992IM5X-1.5/NOPB	Active	Production	SOT-23 (DBV) 5	3000 LARGE T&R	Yes	SN	Level-1-260C-UNLIM	-40 to 125	LFBB
LP2992IM5X-1.8/NO.A	Active	Production	SOT-23 (DBV) 5	3000 LARGE T&R	Yes	SN	Level-1-260C-UNLIM	-40 to 125	LFCEB
LP2992IM5X-1.8/NOPB	Active	Production	SOT-23 (DBV) 5	3000 LARGE T&R	Yes	SN	Level-1-260C-UNLIM	-40 to 125	LFCEB
LP2992IM5X-2.5/NO.A	Active	Production	SOT-23 (DBV) 5	3000 LARGE T&R	Yes	SN	Level-1-260C-UNLIM	-40 to 125	LFDB
LP2992IM5X-2.5/NOPB	Active	Production	SOT-23 (DBV) 5	3000 LARGE T&R	Yes	SN	Level-1-260C-UNLIM	-40 to 125	LFDB
LP2992IM5X-3.3/NO.A	Active	Production	SOT-23 (DBV) 5	3000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	LFEB
LP2992IM5X-3.3/NO.B	Active	Production	SOT-23 (DBV) 5	3000 LARGE T&R	-	Call TI	Call TI	-40 to 125	
LP2992IM5X-3.3/NOPB	Active	Production	SOT-23 (DBV) 5	3000 LARGE T&R	Yes	NIPDAU SN	Level-1-260C-UNLIM	-40 to 125	LFEB
LP2992IM5X-5.0/NO.A	Active	Production	SOT-23 (DBV) 5	3000 LARGE T&R	Yes	SN	Level-1-260C-UNLIM	-40 to 125	LFEB

Orderable part number	Status (1)	Material type (2)	Package Pins	Package qty Carrier	RoHS (3)	Lead finish/ Ball material (4)	MSL rating/ Peak reflow (5)	Op temp (°C)	Part marking (6)
LP2992IM5X-5.0/NOPB	Active	Production	SOT-23 (DBV) 5	3000 LARGE T&R	Yes	SN	Level-1-260C-UNLIM	-40 to 125	LFFB

- ⁽¹⁾ **Status:** For more details on status, see our [product life cycle](#).
- ⁽²⁾ **Material type:** When designated, preproduction parts are prototypes/experimental devices, and are not yet approved or released for full production. Testing and final process, including without limitation quality assurance, reliability performance testing, and/or process qualification, may not yet be complete, and this item is subject to further changes or possible discontinuation. If available for ordering, purchases will be subject to an additional waiver at checkout, and are intended for early internal evaluation purposes only. These items are sold without warranties of any kind.
- ⁽³⁾ **RoHS values:** Yes, No, RoHS Exempt. See the [TI RoHS Statement](#) for additional information and value definition.
- ⁽⁴⁾ **Lead finish/Ball material:** Parts may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.
- ⁽⁵⁾ **MSL rating/Peak reflow:** The moisture sensitivity level ratings and peak solder (reflow) temperatures. In the event that a part has multiple moisture sensitivity ratings, only the lowest level per JEDEC standards is shown. Refer to the shipping label for the actual reflow temperature that will be used to mount the part to the printed circuit board.
- ⁽⁶⁾ **Part marking:** There may be an additional marking, which relates to the logo, the lot trace code information, or the environmental category of the part.

Multiple part markings will be inside parentheses. Only one part marking contained in parentheses and separated by a "~" will appear on a part. If a line is indented then it is a continuation of the previous line and the two combined represent the entire part marking for that device.

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TAPE AND REEL INFORMATION



*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
LP2992AILD-1.5/NOPB	WSO	NGD	6	1000	177.8	12.4	3.6	3.2	1.0	8.0	12.0	Q1
LP2992AILD-1.8/NOPB	WSO	NGD	6	1000	177.8	12.4	3.6	3.2	1.0	8.0	12.0	Q1
LP2992AILD-1.8/NOPB	WSO	NGD	6	1000	180.0	12.4	3.6	3.2	1.0	8.0	12.0	Q1
LP2992AILD-3.3/NOPB	WSO	NGD	6	1000	177.8	12.4	3.6	3.2	1.0	8.0	12.0	Q1
LP2992AILD-3.3/NOPB	WSO	NGD	6	1000	180.0	12.4	3.6	3.2	1.0	8.0	12.0	Q1
LP2992AILD-5.0/NOPB	WSO	NGD	6	1000	177.8	12.4	3.6	3.2	1.0	8.0	12.0	Q1
LP2992AILD-5.0/NOPB	WSO	NGD	6	1000	180.0	12.4	3.6	3.2	1.0	8.0	12.0	Q1
LP2992AILD-3.3/NOPB	WSO	NGD	6	4500	330.0	12.4	3.6	3.2	1.0	8.0	12.0	Q1
LP2992AILD-3.3/NOPB	WSO	NGD	6	4500	330.0	12.4	3.6	3.2	1.0	8.0	12.0	Q1
LP2992AILD-5.0/NOPB	WSO	NGD	6	4500	330.0	12.4	3.6	3.2	1.0	8.0	12.0	Q1
LP2992AILD-5.0/NOPB	WSO	NGD	6	4500	330.0	12.4	3.6	3.2	1.0	8.0	12.0	Q1
LP2992AIM5-1.5/NOPB	SOT-23	DBV	5	1000	178.0	8.4	3.2	3.2	1.4	4.0	8.0	Q3
LP2992AIM5-1.8/NOPB	SOT-23	DBV	5	3000	180.0	8.4	3.2	3.2	1.4	4.0	8.0	Q3
LP2992AIM5-1.8/NOPB	SOT-23	DBV	5	3000	178.0	8.4	3.2	3.2	1.4	4.0	8.0	Q3
LP2992AIM5-2.5/NOPB	SOT-23	DBV	5	3000	178.0	8.4	3.2	3.2	1.4	4.0	8.0	Q3
LP2992AIM5-2.5/NOPB	SOT-23	DBV	5	3000	180.0	8.4	3.2	3.2	1.4	4.0	8.0	Q3

Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
LP2992AIM5-3.3/NOPB	SOT-23	DBV	5	3000	180.0	8.4	3.2	3.2	1.4	4.0	8.0	Q3
LP2992AIM5-3.3/NOPB	SOT-23	DBV	5	3000	178.0	8.4	3.2	3.2	1.4	4.0	8.0	Q3
LP2992AIM5-3.3/NOPB	SOT-23	DBV	5	3000	180.0	8.4	3.2	3.2	1.4	4.0	8.0	Q3
LP2992AIM5-5.0/NOPB	SOT-23	DBV	5	3000	178.0	8.4	3.2	3.2	1.4	4.0	8.0	Q3
LP2992AIM5-5.0/NOPB	SOT-23	DBV	5	3000	180.0	8.4	3.2	3.2	1.4	4.0	8.0	Q3
LP2992AIM5X-1.5/NOPB	SOT-23	DBV	5	3000	178.0	8.4	3.2	3.2	1.4	4.0	8.0	Q3
LP2992AIM5X-1.8/NOPB	SOT-23	DBV	5	3000	178.0	8.4	3.2	3.2	1.4	4.0	8.0	Q3
LP2992AIM5X-2.5/NOPB	SOT-23	DBV	5	3000	178.0	8.4	3.2	3.2	1.4	4.0	8.0	Q3
LP2992AIM5X-3.3/NOPB	SOT-23	DBV	5	3000	178.0	8.4	3.2	3.2	1.4	4.0	8.0	Q3
LP2992AIM5X-3.3/NOPB	SOT-23	DBV	5	3000	180.0	8.4	3.2	3.2	1.4	4.0	8.0	Q3
LP2992AIM5X-3.3/NOPB	SOT-23	DBV	5	3000	180.0	8.4	3.2	3.2	1.4	4.0	8.0	Q3
LP2992AIM5X-5.0/NOPB	SOT-23	DBV	5	3000	180.0	8.4	3.2	3.2	1.4	4.0	8.0	Q3
LP2992AIM5X-5.0/NOPB	SOT-23	DBV	5	3000	178.0	8.4	3.2	3.2	1.4	4.0	8.0	Q3
LP2992ILD-1.8/NOPB	WSON	NGD	6	1000	177.8	12.4	3.6	3.2	1.0	8.0	12.0	Q1
LP2992ILD-1.8/NOPB	WSON	NGD	6	1000	180.0	12.4	3.6	3.2	1.0	8.0	12.0	Q1
LP2992ILD-2.5/NOPB	WSON	NGD	6	1000	177.8	12.4	3.6	3.2	1.0	8.0	12.0	Q1
LP2992ILD-3.3/NOPB	WSON	NGD	6	1000	177.8	12.4	3.6	3.2	1.0	8.0	12.0	Q1
LP2992ILD-3.3/NOPB	WSON	NGD	6	1000	180.0	12.4	3.6	3.2	1.0	8.0	12.0	Q1
LP2992ILD-5.0/NOPB	WSON	NGD	6	1000	177.8	12.4	3.6	3.2	1.0	8.0	12.0	Q1
LP2992ILD-5.0/NOPB	WSON	NGD	6	1000	180.0	12.4	3.6	3.2	1.0	8.0	12.0	Q1
LP2992ILDx-1.5/NOPB	WSON	NGD	6	4500	330.0	12.4	3.6	3.2	1.0	8.0	12.0	Q1
LP2992ILDx-1.5/NOPB	WSON	NGD	6	4500	330.0	12.4	3.6	3.2	1.0	8.0	12.0	Q1
LP2992ILDx-3.3/NOPB	WSON	NGD	6	4500	330.0	12.4	3.6	3.2	1.0	8.0	12.0	Q1
LP2992ILDx-3.3/NOPB	WSON	NGD	6	4500	330.0	12.4	3.6	3.2	1.0	8.0	12.0	Q1
LP2992ILDx-5.0/NOPB	WSON	NGD	6	4500	330.0	12.4	3.6	3.2	1.0	8.0	12.0	Q1
LP2992IM5-1.5/NOPB	SOT-23	DBV	5	1000	178.0	8.4	3.2	3.2	1.4	4.0	8.0	Q3
LP2992IM5-1.8/NOPB	SOT-23	DBV	5	3000	178.0	8.4	3.2	3.2	1.4	4.0	8.0	Q3
LP2992IM5-1.8/NOPB	SOT-23	DBV	5	3000	180.0	8.4	3.2	3.2	1.4	4.0	8.0	Q3
LP2992IM5-2.5/NOPB	SOT-23	DBV	5	1000	178.0	8.4	3.2	3.2	1.4	4.0	8.0	Q3
LP2992IM5-3.0/NOPB	SOT-23	DBV	5	1000	178.0	8.4	3.2	3.2	1.4	4.0	8.0	Q3
LP2992IM5-3.3/NOPB	SOT-23	DBV	5	3000	180.0	8.4	3.2	3.2	1.4	4.0	8.0	Q3
LP2992IM5-3.3/NOPB	SOT-23	DBV	5	3000	180.0	8.4	3.2	3.2	1.4	4.0	8.0	Q3
LP2992IM5-3.3/NOPB	SOT-23	DBV	5	3000	178.0	8.4	3.2	3.2	1.4	4.0	8.0	Q3
LP2992IM5-5.0/NOPB	SOT-23	DBV	5	3000	180.0	8.4	3.2	3.2	1.4	4.0	8.0	Q3
LP2992IM5-5.0/NOPB	SOT-23	DBV	5	3000	178.0	8.4	3.2	3.2	1.4	4.0	8.0	Q3
LP2992IM5X-1.5/NOPB	SOT-23	DBV	5	3000	178.0	8.4	3.2	3.2	1.4	4.0	8.0	Q3
LP2992IM5X-1.8/NOPB	SOT-23	DBV	5	3000	180.0	8.4	3.2	3.2	1.4	4.0	8.0	Q3
LP2992IM5X-1.8/NOPB	SOT-23	DBV	5	3000	178.0	8.4	3.2	3.2	1.4	4.0	8.0	Q3
LP2992IM5X-2.5/NOPB	SOT-23	DBV	5	3000	178.0	8.4	3.2	3.2	1.4	4.0	8.0	Q3
LP2992IM5X-3.3/NOPB	SOT-23	DBV	5	3000	180.0	8.4	3.2	3.2	1.4	4.0	8.0	Q3
LP2992IM5X-3.3/NOPB	SOT-23	DBV	5	3000	180.0	8.4	3.2	3.2	1.4	4.0	8.0	Q3

Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
LP2992IM5X-3.3/NOPB	SOT-23	DBV	5	3000	178.0	8.4	3.2	3.2	1.4	4.0	8.0	Q3
LP2992IM5X-5.0/NOPB	SOT-23	DBV	5	3000	180.0	8.4	3.2	3.2	1.4	4.0	8.0	Q3
LP2992IM5X-5.0/NOPB	SOT-23	DBV	5	3000	178.0	8.4	3.2	3.2	1.4	4.0	8.0	Q3

TAPE AND REEL BOX DIMENSIONS

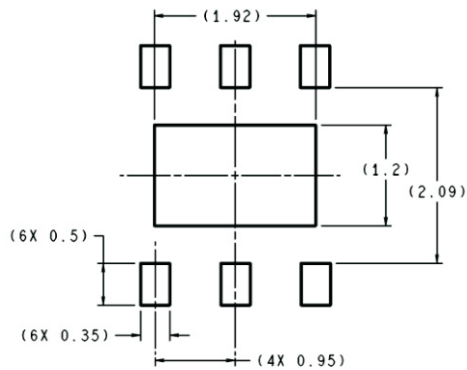


*All dimensions are nominal

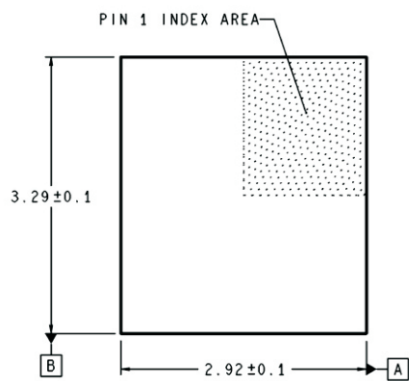
Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
LP2992AILD-1.5/NOPB	WSO	NGD	6	1000	208.0	191.0	35.0
LP2992AILD-1.8/NOPB	WSO	NGD	6	1000	208.0	191.0	35.0
LP2992AILD-1.8/NOPB	WSO	NGD	6	1000	213.0	191.0	35.0
LP2992AILD-3.3/NOPB	WSO	NGD	6	1000	208.0	191.0	35.0
LP2992AILD-3.3/NOPB	WSO	NGD	6	1000	213.0	191.0	35.0
LP2992AILD-5.0/NOPB	WSO	NGD	6	1000	208.0	191.0	35.0
LP2992AILD-5.0/NOPB	WSO	NGD	6	1000	213.0	191.0	35.0
LP2992AILD-3.3/NOPB	WSO	NGD	6	4500	356.0	356.0	36.0
LP2992AILD-3.3/NOPB	WSO	NGD	6	4500	367.0	367.0	38.0
LP2992AILD-5.0/NOPB	WSO	NGD	6	4500	356.0	356.0	36.0
LP2992AILD-5.0/NOPB	WSO	NGD	6	4500	367.0	367.0	38.0
LP2992AIM5-1.5/NOPB	SOT-23	DBV	5	1000	208.0	191.0	35.0
LP2992AIM5-1.8/NOPB	SOT-23	DBV	5	3000	210.0	185.0	35.0
LP2992AIM5-1.8/NOPB	SOT-23	DBV	5	3000	208.0	191.0	35.0
LP2992AIM5-2.5/NOPB	SOT-23	DBV	5	3000	208.0	191.0	35.0
LP2992AIM5-2.5/NOPB	SOT-23	DBV	5	3000	210.0	185.0	35.0
LP2992AIM5-3.3/NOPB	SOT-23	DBV	5	3000	210.0	185.0	35.0
LP2992AIM5-3.3/NOPB	SOT-23	DBV	5	3000	208.0	191.0	35.0

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
LP2992AIM5-3.3/NOPB	SOT-23	DBV	5	3000	210.0	185.0	35.0
LP2992AIM5-5.0/NOPB	SOT-23	DBV	5	3000	208.0	191.0	35.0
LP2992AIM5-5.0/NOPB	SOT-23	DBV	5	3000	210.0	185.0	35.0
LP2992AIM5X-1.5/NOPB	SOT-23	DBV	5	3000	208.0	191.0	35.0
LP2992AIM5X-1.8/NOPB	SOT-23	DBV	5	3000	208.0	191.0	35.0
LP2992AIM5X-2.5/NOPB	SOT-23	DBV	5	3000	208.0	191.0	35.0
LP2992AIM5X-3.3/NOPB	SOT-23	DBV	5	3000	208.0	191.0	35.0
LP2992AIM5X-3.3/NOPB	SOT-23	DBV	5	3000	210.0	185.0	35.0
LP2992AIM5X-3.3/NOPB	SOT-23	DBV	5	3000	210.0	185.0	35.0
LP2992AIM5X-5.0/NOPB	SOT-23	DBV	5	3000	210.0	185.0	35.0
LP2992AIM5X-5.0/NOPB	SOT-23	DBV	5	3000	208.0	191.0	35.0
LP2992ILD-1.8/NOPB	WSON	NGD	6	1000	208.0	191.0	35.0
LP2992ILD-1.8/NOPB	WSON	NGD	6	1000	213.0	191.0	35.0
LP2992ILD-2.5/NOPB	WSON	NGD	6	1000	208.0	191.0	35.0
LP2992ILD-3.3/NOPB	WSON	NGD	6	1000	208.0	191.0	35.0
LP2992ILD-3.3/NOPB	WSON	NGD	6	1000	213.0	191.0	35.0
LP2992ILD-5.0/NOPB	WSON	NGD	6	1000	208.0	191.0	35.0
LP2992ILD-5.0/NOPB	WSON	NGD	6	1000	213.0	191.0	35.0
LP2992ILDX-1.5/NOPB	WSON	NGD	6	4500	367.0	367.0	38.0
LP2992ILDX-1.5/NOPB	WSON	NGD	6	4500	356.0	356.0	36.0
LP2992ILDX-3.3/NOPB	WSON	NGD	6	4500	356.0	356.0	36.0
LP2992ILDX-3.3/NOPB	WSON	NGD	6	4500	367.0	367.0	38.0
LP2992ILDX-5.0/NOPB	WSON	NGD	6	4500	356.0	356.0	36.0
LP2992IM5-1.5/NOPB	SOT-23	DBV	5	1000	208.0	191.0	35.0
LP2992IM5-1.8/NOPB	SOT-23	DBV	5	3000	208.0	191.0	35.0
LP2992IM5-1.8/NOPB	SOT-23	DBV	5	3000	210.0	185.0	35.0
LP2992IM5-2.5/NOPB	SOT-23	DBV	5	1000	208.0	191.0	35.0
LP2992IM5-3.0/NOPB	SOT-23	DBV	5	1000	208.0	191.0	35.0
LP2992IM5-3.3/NOPB	SOT-23	DBV	5	3000	210.0	185.0	35.0
LP2992IM5-3.3/NOPB	SOT-23	DBV	5	3000	210.0	185.0	35.0
LP2992IM5-3.3/NOPB	SOT-23	DBV	5	3000	208.0	191.0	35.0
LP2992IM5-5.0/NOPB	SOT-23	DBV	5	3000	210.0	185.0	35.0
LP2992IM5-5.0/NOPB	SOT-23	DBV	5	3000	208.0	191.0	35.0
LP2992IM5X-1.5/NOPB	SOT-23	DBV	5	3000	208.0	191.0	35.0
LP2992IM5X-1.8/NOPB	SOT-23	DBV	5	3000	210.0	185.0	35.0
LP2992IM5X-1.8/NOPB	SOT-23	DBV	5	3000	208.0	191.0	35.0
LP2992IM5X-2.5/NOPB	SOT-23	DBV	5	3000	208.0	191.0	35.0
LP2992IM5X-3.3/NOPB	SOT-23	DBV	5	3000	210.0	185.0	35.0
LP2992IM5X-3.3/NOPB	SOT-23	DBV	5	3000	210.0	185.0	35.0
LP2992IM5X-3.3/NOPB	SOT-23	DBV	5	3000	208.0	191.0	35.0
LP2992IM5X-5.0/NOPB	SOT-23	DBV	5	3000	210.0	185.0	35.0
LP2992IM5X-5.0/NOPB	SOT-23	DBV	5	3000	208.0	191.0	35.0

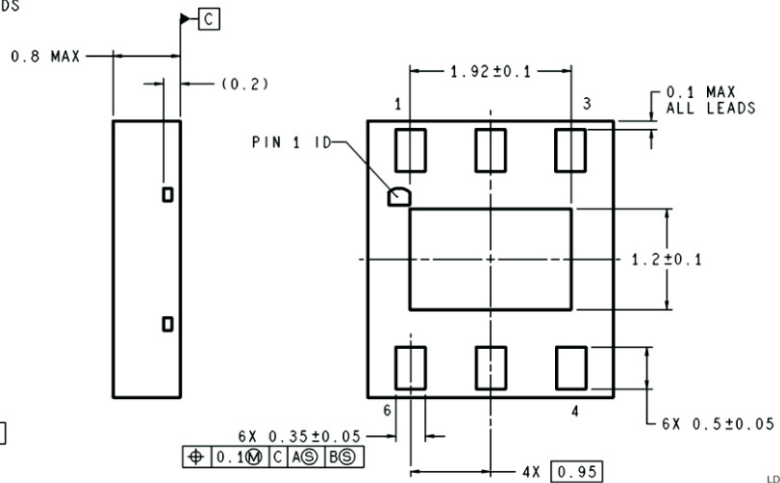
NGD0006A



RECOMMENDED LAND PATTERN
1:1 RATIO WITH PKG SOLDER PADS



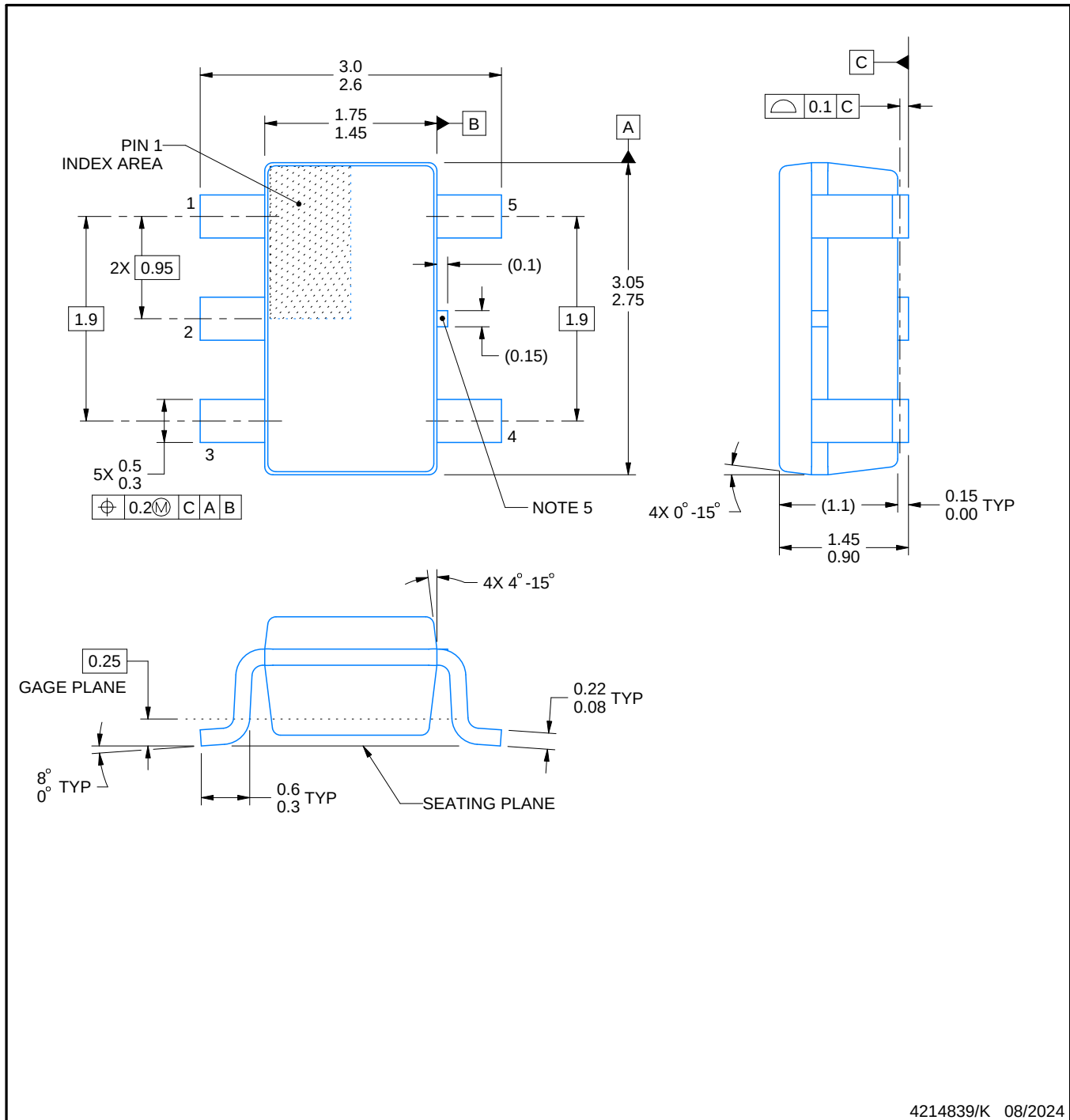
DIMENSIONS ARE IN MILLIMETERS



LDE06A (Rev A)

DBV0005A**PACKAGE OUTLINE****SOT-23 - 1.45 mm max height**

SMALL OUTLINE TRANSISTOR

**NOTES:**

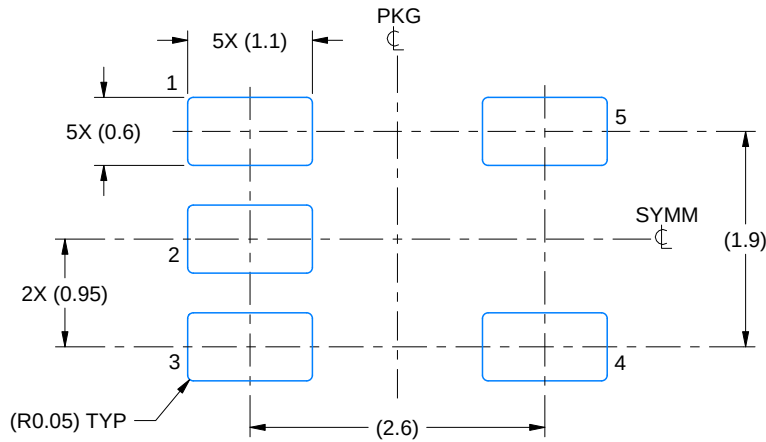
1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. Reference JEDEC MO-178.
4. Body dimensions do not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.25 mm per side.
5. Support pin may differ or may not be present.

EXAMPLE BOARD LAYOUT

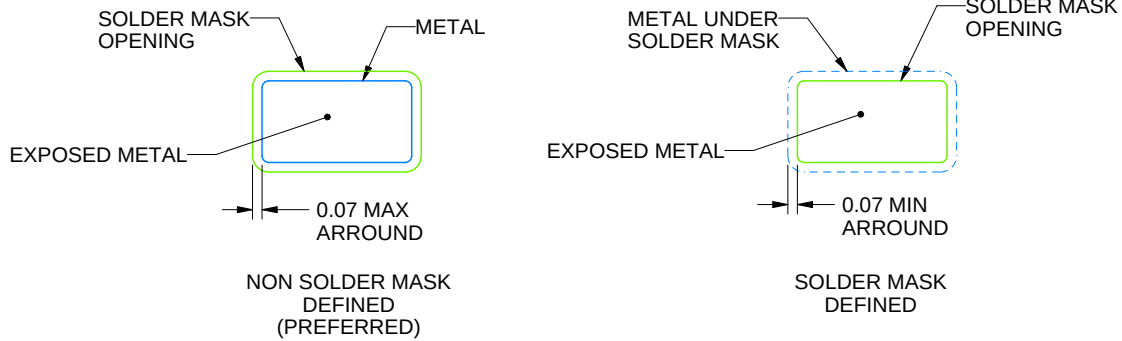
DBV0005A

SOT-23 - 1.45 mm max height

SMALL OUTLINE TRANSISTOR



LAND PATTERN EXAMPLE
EXPOSED METAL SHOWN
SCALE:15X



SOLDER MASK DETAILS

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NOTES: (continued)

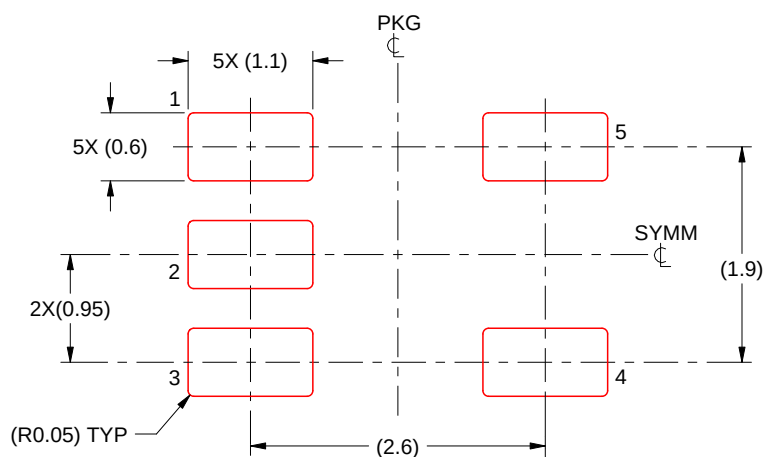
6. Publication IPC-7351 may have alternate designs.
7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.

EXAMPLE STENCIL DESIGN

DBV0005A

SOT-23 - 1.45 mm max height

SMALL OUTLINE TRANSISTOR



SOLDER PASTE EXAMPLE
BASED ON 0.125 mm THICK STENCIL
SCALE:15X

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NOTES: (continued)

8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
9. Board assembly site may have different recommendations for stencil design.

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